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#### HYDROTHERMAL GROWTH OF ZINC CHIDE CHYSTALS

Roch R. Monchamp, Pichard C. Puttbach, J.W. Mielson

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#### PORTHORD

This Final Technical Report covers all work performed under Contracts AF33(657)-8795 and AF33(615)-2228 from 1 June 1962 to 31 December 1966. The manuscript was released by the authors in May 1967, for publication as an AFML Technical Report.

These contracts with Airtron, a division of Litton Industries, Morris Flains, New Jersey, were initiated under Manufacturing Methods Project 7-988, "The Evirothermal Growth of Zino Gride Grystals". It was accomplished under the technical direction of Mr. Robert G. Bratt of the Electronice Branch (MATE), Manufacturing Technology Division, Air Force Materials Laboratory, Wright-Fatterson Air Force Base, Chio.

Closely related efforts are covered under MOP No. 8-132, "The Eydrothermal Growth of Large Ruby Single Crystals".

Dr. Boch R. Monchamp, Manager, Crystal Growth Research and Development, of Airtron's Solid State Laboratory, was the Project Director. Others who cooperated in the research and in the preparation of the report weres Dr. J. W. Mielsen, Manager, Solid State Laboratory, and Richard G. Puttbach, Project Engineer. This report has been given Airtron's report number R11-534.

This project has been accomplished as a part of the Air Force Manufacture ing Methods Program, the primary objective of which is to develop, on a timely basis. manufacturing processes, techniques and equipment for use in economical production of USAF materials and components. The program encompasses the following technical areas.

Design of pilot line for ZnO orystals by the molton salt technique, the hydrothermal growth of large ZnO orystals, the hydrothermal growth of doped ZnO orystals.

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Suggestions concerning additional Manufacturing Methods development required on this or other subjects will be appreciated.

This technical report has been reviewed and is approved.

CHARLES H. HELSON Assistant Chief Manufacturing Technology Division

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#### ABSTRACT

A pilot line for the production of large high quality ZnO single crystals was established and many large crystals were produced. The pilot line can be divided into two units, 1) a molton salt line for the production of seed plates to be used in 2) the hydrothermal crystal growth pilot line. The design and construction of both lines were successfully completed and functioned as planned.

The molten salt crystal growth effort was not as successful as had been anticipated. Large area, high quality crystals could not be made reproducibly by this technique. The most apparent reasons for the failure to do so rests in thermal gradient control during the growth cycle and/or the presence or absence of impurities in the melt.

Although these problems were not completely resolved, the wolten salt pilot line did yield sufficient plates for the initial portion of the hydrothermal crystal growth program.

Once growth conditions and procedures were established in the hydrothermal pilot line, the hydrothermally grown crystals were sectioned and used as seeds for subsequent runs. The area of the crystals were increased by continued growth until large high quality crystals weighing more than 150 grams could be grown on such seeds within reasonable operating times.

One problem arose which had not been encountered in previous hydrothermal systems. It was found that the silver liner or can was corrosively attacked during the course of the growth cycle. The silver which was dissolved in the fluid in the nutrient chamber would also be deposited in the crystals in the growth chamber. This problem was selved by adding a reducing agent (metallic zinc) to the reactants. The cause of the corrosion apparently is due to the presence of oxygen dissolved in the solvent and as air entrapped in closure of the can. The reason this phenomenon had not been observed in other small systems using noble metal liners is that no other similar system has been scaledup to the ZnO size. The solution of this problem for the ZnO case will undoubtedly be of value to other large hydrothermal crystal growth systems.

In addition to the growth of the large crystals many smaller crystals were grown which were doped with copper to give resistivities in the  $10^2 - 10^4$  cm range. This is the range most desirable for acoustical amplifier devices.

Other doping studies indicate a wide variation of resistivities within the virgin crystal, and from crystal to crystal within a run. After heat treatment, however, the variation of resistivity is reduced to an order of magnitude or less. It was also observed that impurities not detected by spectrographic analysis may be as important in determining the resultant resistivity as deliberate doping additions and growth conditions.

#### Abstract (Continued)

During the course of these contracts many samples of hydrothermally grown ZnO were given to scientists and engineers in government, industrial and university laboratories for measurement of the fundamental properties of ZnO and for device design and development.

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#### 1.0 INTRODUCTION

The discovery by Hutson<sup>4</sup> that sing oxide has a piecelectric compling coefficient of 0.4, or four times that of quarts, stimulated mode interest in this material, and work is underway in many inhoratories to use crystals of sinc oxide both to improve existing devices and build new ones. One existing dovice which will be improved by using sinc oxide is the ultrasonic  $\rightarrow$  ay line.

#### 1.1 Applications

At present, ultrasonic delay lines for applications requiring long delays, of the order of milliseconds or a little less, use either crystalline quarts, or barium titanate ceramic transducers. The r-f signal is impressed upon a driving transducer which resonates and sende a sound wave through a delay medium; usually fuesd silics, ustil, perhaps after several reflections, the sound wave strikes a receiving piesoelectric transducer which changes 'he signal back to r-f. Both quarts and barium titanate ceramics have serious shortcomings when long delays at high frequencies are desired.

Crystalline quartz is limited in the length of delay time that it can achieve. The piezoelectric coupling coefficient, k, is only 0.1 The power of a transducer depends on the square of this coefficient and the length of delay which can be achieved depends strongly on the power available since attenuation of ultrasonic waves in silica is severe. With k = 0.1, quartz is limited to short delay applications. On the other hand, quartz can be lapped into very precise and very thin plates. Since the resonant frequency of a transducer is inversely proportional to its thickness, quartz can be used at high frequencies, around 100 Mc. This is for the fundamental mode. Higher modes can be set up, but, again because of the low k, the efficiency of higher mode transducers is very low.

In the case of barium titanate ceramics, the problem is not with delay time but the upper frequency at which the delay lines can operate. Barium titanate ceramics have coupling coefficients of 0.35 and higher. With these high coefficients, delay times of 6000 microseconds have been achieved. However, the dielectric constant of these ceramics is about 500. Thus, as the transducers are made thinner for higher frequency operation, the capacitance becomes very high, and the impedance match between transducers, which is necessary for operation of the device, becomes impossible to achieve. This limits the upper frequency for delay lines having barium titanate transducers to 15 Mc.

Zinc oxide solves the problems of quartz and barium titanate simultaneously. It has a coupling coefficient of 0.4 and a dielectric constant much nearer that of quartz than of  $BaTiO_{2}$ . Its dielectric constant is between 9 and 12, depending on frequency. It can also be ground and lapped to close tolerances like quartz. Thus, it appears that delay lines having 3-6000 u sec. delays a frequencies over 100 Mc are possible. Indeed, with the higher k, it is at least possible that

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#### Introduction (Continued)

in some applications higher modes could be used in spite of the higher losses. This would raise the frequency of operation much higher.

A second very promising use of ZnO is in the very new ultraschic amplifier reported by Hutson, McPee and White.<sup>2,3</sup> In this device a quarts transducer sends a shear wave through a fused silica buffer which is in contact with a piezoelectric semiconductor. (Hutson, <u>et al</u> used cadmium sulfide since that was the only material available in suitable single crystal form.) The semiconductor is in contact with another buffer and a receiving transducer. It was found that when a light of certain intensity was used to excite the proper carrier concentration in CdS, a drift field pulse was applied to the CdS in the direction of the shear wave propagation, a gain was observed in the ultrasonic signal. Gains of 18 db at 15 Mc/sec and 38 db at 45 Mc/sec were reported for a 7mm sample of CdS.

A.R. Hutson<sup>3</sup> has suggested that ZnO would be superior to CdS as the semiconducting transducer because of its high coupling coefficient. It could also serve as the driving transducer.

Two specific applications for ZnO have been discussed. There are no doubt many others. Probably quarts and ceramic piezoelectric can be replaced with ZnO to great advantage in other devices. But in all applications large, sound, single crystals of ZnO will be required.

This report contains a description of the development of the manufacturing methods, techniques and equipment required for the hydrothermal production of high quality, large single crystals of sinc oxide.

#### 1.2 Properties

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Zinc oxide in the pure state is a clear water white oxide having the wurtzite structure (hexagonal.) As normally prepared it is an n-type semiconductor. Resistivities are observed as low as 5 ohm cm in newly grown crystals. This resistivity can be raised or lowered by various treatments with zinc, hydrogen or oxygen. This fact, coupled with the high energy gap (estimated at 3.3 ev), originally led to the hope that zinc oxide would be suitable for semiconductor devices applications.

The use of ZnO in semiconductor devices has been curtailed because to date no one has succeeded in making it p-type. Thus p-n junctions cannot be made. In an effort to make p-type material, Lander<sup>5</sup> studied the behavior of various ions in the sinc oxide lattice. He discovered that Li<sup>+</sup> will act as an acceptor in ZnO and will compensate the n-type conductivity so that the material will become insulating, although it will not become p-type. This work, plue the growth of larger crystals, led directly to Hutson's discovery of the large piezoelectric effect in ZnO. It is the compensated ZnO which exhibits a large effect.

#### Introduction (Continued)

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The mechanical Q of sinc oxide is not as high as quarts but is far higher than titanate ceramics. Charlton<sup>6</sup> has measured values varying from 10<sup>5</sup> to over 10<sup>6</sup>, depending on composition, on crystals grown at Airtron. Charlton has also found that the temperature stability of the resonant frequency of a sinc oxide (0001) disk oscillating in the compressional mode is only a little poorer than a similar quarts resonator. Since no other type of oscillator has been made of sinc oxide because of a lack of suitable crystals, it is not known if certain cuts will possess the high temperature stabil<sup>4</sup> ty observed in some quarts oscillators. The temperature stability of 200 appears to be less than that of some titanate ceramics.<sup>6</sup> This would not be serious in two-transducer devices or in those where extreme temperature stability was unnecessary.

#### 1.3 Growth Method

Zinc oxide is known for its high vapor pressure and its rapid sublimation. It has not been observed, to our knowledge, in the molten state. The vapor phase has proved very difficult as a growth medium for ZnO in that it is not possible to grow large crystals reproducibly.

It appeared at the time of the beginning of this work that a combination of molten salt (for seeds)<sup>7</sup> and hydrothermal<sup>8</sup> techniques should yield large crystals reproducibly for the first time.

The growth of ZnO from the vapor phase yields crystals which are of a needle type habit. The ratio of axis length to diameter is about 50 to 1 in these crystals normally, although more truncated crystals are sometimes obtained. The largest diameters are about 5mm. The needle form is due to differences in growth rates between the <0001> direction and those perpendicular to it. While possibly suitable for some acoustical amplifier uses, the small size of such crystals make them unsuitable for large area transducer type devices.

On the other hand the molten salt crystals grow with exactly opposite differences in rates. The lateral growth rates are about 50 times greater than the <0001> growth thus yield large area flat plates which are ideally suited for hydrothermal seed crystals. It has been found that in the hydrothermal system nearly more equal growth rates are obtained in the lateral and <0001> directicus.

In order to produce ZnO seed plate crystals by the molten salt technique a platinum can is charged with about 20 mole percent ZnO and PbF<sub>2</sub> powders. The can and contents are then heated to 1150°C and held at that temperature for 2 hours. The melt is cooled to 1050°C at a rate of 3-5°C/hour after which the can is withdrawn and the flux poured off from the crystals.

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#### Introduction (Continued)

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Normally, crystal growth from aqueous solution is carried out at atmospheric pressure and temperatures close to room temperature. The hydrothermal technique is one which allows crystallisation to be carried out under a wide range of temperatures and pressures. The higher pressures and temperatures employed in this method provide a means of obtaining solubilities and nucleating conditions for crystals which would be difficult to grow using other techniques.

In operation, an aqueous solution is held at x high temperature and pressure in order to dissolve the source material (nutrient) in one part of the system, transport the dissolved nutrient to another part of the system and deposit it onto a seed crystal epitaxially. The process is carried out in vertically mounted, scaled autoclaves along which a temperature difference ( $\Delta T$ ) is imposed between the top and bottom. The nutrient is usually placed in the bottom, hotter portion of the autoclave chamber while the properly oriented single crystal seeds are suspended in the upper, cooler region as in Figure 1.

The aqueous solvent in the region of the nutrient becomes saturated with nutrient which is then transported by thermal convection to the cooler portion of the autoclave. In this region, the solution is supersaturated with respect to the seed crystals and, therefore, deposits the solute on the seeds. The now cooler and depleted solvent returns to the nutrient region by convection where, not now being saturated, it may again dissolve the nutrient material. Obviously, the process is continuous and stops only when the nutrient supply is enhausted.

More detailed descriptions of the hydrothermal process and equipment can be found in review articles by Laudise and Nielsen,<sup>9</sup> and Laudise.<sup>10</sup> These articles, particularly that of Laudise and Nielsen, also emphasize the hydrothermal process for quarts work.

While we were in the process of setting up the pilot line, Laudise, Kolb and Caporaso,<sup>8</sup> published their first paper concerning the hydrothermal growth of zinc oxide crystals. They used small silverlined Morey type vessels and so all the data they presented was not easily translated to the larger vessel of the pilot line. Their solvent, its concentration, temperature range data, etc., did provide an excellent starting place. In fact, other than working at higher pressures, the growth parameters currently used are not too different from the original data of Laudise et al.



#### 2.0 PILOT LINE

#### 2.1 Molten Salt

#### 2.1.1 Floor Layout and Equipment

The floor plan for the ZnO crystal growth pilot line is shown in Figure 2. The figure shows the location of our three inch wolten salt furnaces, the 10 inch furnace, the hydrothermal pit and general work areas. The molten salt crystal growth was mostly performed in the ten inch and three inch furnaces described in the following section.

#### 2.1.2 The Ten Inch Furnace

The metal shell of a vertical 10 inch I.D. American Electric<sup>+</sup> globar furnace was used to house a cerasic interior, see Figure 3. The bottom of the metal shell was welded; however, the top was only bolted down as was, therefore, easily removed. Thus, the furnace interior could be inserted from the top. The furnace interior, shown in Figure 4, and fabricated by Research and Development Co.<sup>±</sup> was made in two pieces. The dotted line in Figure 4 shows the individual sections (the alumina core is one piece). The furnace consists of the following:

1. A cast alumina core and cast furnace lining.

2. A.P. Green's type Sair-set bonding cement.

3. High temperature firebrick, type K-30 and medium temperature insulating brick, type K-20, both supplied by Babcock and Wilcox.<sup>++</sup>

The high purity cast alumina core and alumina lining are necessary to withstand the PbF<sub>2</sub> vapors at elevated temperatures. The pedestal and plug are also cast from high purity alumina and are supplied by Research and Development Co.<sup>1</sup> A typical 10 inch furnace pedestal and plug are shown in Figure 5. Positioning of the pedestal was varied during the course of the work as indicated in Tables II and III of Section 3.1.2.

Using normal furnace loading, the inner furnace parts had to be changed every 6 to 9 months. The tearing down and rebuilding usually took one technician about one week to accomplish after the

- + American Electric Furnace Co., Boston, Massachusetts.
- + Research and Development Co., New Market, New Jersey.
- A.P. Green Firebrick Co., Pennsylvania.
- ++ Babcock and Wilcox, New York 17, New York.

++ Research and Development Co., New Market, New Jersey.

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## Figure 3 - 10 Inch I.D. Furnace



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#### Pilot Line (Continued)

furnace had cooled to room temperature (cooling to room temperature would take 4 days.) Normally, the core was considerably swelled and the plug was bonded to the upper portion of the core due to solvent attack; thus meither the plug nor core was easily removed. The most successful method used was to forcibly extract the plug plus upper core half by means of an overhead block and tackle. The lower portion of the core was chipped away with a hammer. The remainder of the furnace insides are either lifted out or chipped away depending upon the extent of solvent attack. Once the furnace was reasonabled, a slow initial warm-up cycle was necessary in order to remove water and prevent cracking of ceramic parts. The furnace was allowed to heat to 250 - 300°C a. a rate of 15°C per hour and then held at that temperature for 24 hours, after which the furnace was brought rapidly to temperature.

Four 0.020 inch dirmeter platinum vs. platinum 13 percent rhodium thermocouples are used to either control the furnace or indicate the temperature at a desired location. The control thermocouple and one indicating thermocouple are located in the heating element region. These are shown in Figure 4. The control thermocouple is placed in the heating element area in order to sense and adjust temperature fluctuations before they affect crystal growth. A second indicating thermocouple is located in the plug, and the last, but most important thermocouple is located in the pedestal, see Figure 5. The pedestal thermocouple is positioned less than 1/4 inch away from the crucible floor, and was used to indicate "hold" and pour temperatures.

The pedestal thermocouple rotates with the pedestal during the soak period (fast rotation) and cooling cycle (slow rotation). It was, therefore, necessary to provide adequate voltage transmission to the potentiometer while the thermocouple was rotating. This was accomplished through use of a slip ring device which is shown in Figure 6. The thermocouple leads are soldered to brass rings which make continuous friction contact to copper wipers. This device was manufactured at Airtron and enables a continuous indication of the temperature throughout the crystal growth run.

The 10 inch furnace was equipped with an elevator and crucible rotating mechanism, which are shown in Figure 7. The elevator system is used to raise and lower the pedestal in order to insert and remove crystal growth runs. The elevator system is driven by a 3 phase AC motor, Type P, Model D56C, manufactured by Doerr Electric Co.<sup>+</sup> It consists of a pedestal platform which is driven by four rotating screws. The crucible rotating mechanism is used to aid solution of the constituent oxides during the hold period. It consists of chain

Doerr Blectric Co., Cedarsburg, Virginia





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#### Pilot Line (Continued)

driven bearings mounted in the pedestal platform. The motor drive for the rotating system is equipped with an electric clutch to prevent abrupt starting and stopping of the pedestal. The motor, type HB-3P, and electric clutch, Part No. 304374-1, operate as one unit and are supplied by New England Gear Works and Baton Manufacturing Co.-, respectively. The motor drives at 90 rpm to a 1 to 3 gear sprocket reduction which turns the pedestal at 30 rpm. The typical rotating cycle used is described in Section 2.1.6, Seed Crystal Growth Conditions.

Due to the weight of the melt plus crucible (55 to 75 pounds), a special device is needed for the pouring or unloading operation. A drawing of this device is shown in Figure 8. A set of metal jaws insulated with Fiberfrax sheet is clamped onto the crucible and supporting ceramic plate and the pedestal is lowered away. The unloader plus crucible is rolled down a track, then twisted so as to enable the liquid to pour slowly into a sand box.

Heating elements are a major consideration when attempting crystal growth on a large scale. During the earlier runs, Nortona "Hot Rods" and Carborundum "Glo-bars" were used unsuccessfully. These elements were matched to the power input but usually did not last more than 6 to 8 weeks. With a life time of 6 to 8 weeks, it was impossible to be sure that a second run would proceed to composition.

Morganite<sup>++</sup> spiral cut heating elements (manufactured by Crucilite in England) are presently used. These double glazed 1 1/8 inch diameter elements are resistance matched to less than 2 1/2 percent and have an operating lifetime of about 6 months. These elements usually last as long as the furnace lining and are standard for the pilot line.

In order to insure identical aging of the heating elements, it would be ideal to have a completely parallel power hookup. Unfortunately, the available power equipment and the resistances of connercial heating elements are not compatible with such a hookup; therefore, the design shown in Figure 9 was used as an alternative. This alternating two-bank series parallel design should approximate uniform heating even though the two-banks may age differently. The elements are located 45° apart on a 16 inch bolt circle; this places the center of each element 2.5 inches from the outside diameter of the alumina core.

+ New England Gear Works, South Hampton, Connecticut.

- + Baton Manufacturing Co., Kenosha, Wisconsin.
- A Norton Co., Teterboro, New Jersey.
- A Carborundum Co. Niagra Falls, New York.
- ++ Norganite Co., 3302-3320 40th Avenue, Long Island City, New York.





#### Pilot Line (Continued)

The temperature control equipment, saturable reactor, power transformer and strip chart recorder (for temperature read out) were purchased from Minneapolis Honeywell Co.\* The Beck program comtroller was also supplied through Minneapolis Honeywell. These components are shown with the appropriate interconnections to the furnace in Figure 10. Also shown are the elevator and rotating mechanism wiring.

The temperature control is accomplished through use of a platinum, platinum 13 percent rhodium thermocouple. The thermocouple wire is 0.20 inches in diameter, and is Hoglehard's atandard grade. The location of the control thermocouple is shown in Figure 4. All the thermocouples, including the control thermocouple, are insulated with McDanel<sup>2</sup> type AR2T116316 round, double bore insulation. The thermocouple plus insulation is placed in an alumina protection tube, type AFPT 14. The thermocouple is connected to an electronic multbalance recorder controller (see Figure 10), the calibrated accuracy of which is 0.3 percent of the span or  $\pm 0.12$  °C. The actual cooling or temperature lowering is accomplished with a Beck control unit calibrated from 0.3 to 10°C per hour. Unfortunately, the Beck unit can only be used for cooking. Warm-up procedure, either from a cold furnace or after a run has been poured, must be accomplished by a manual control located on the Electro-Volt Controller, (see Figure 10). The warm-up procedure from a cold furnace has been previously described; warming up to "soak" temperature after a pour normally takes from 6 to 10 hours. Furnace power is regulated by the control unit throu 1.50 of a saturable reactor, (see Figure 10).

### 2.1.3 The Three Inch Furnace

The four three inch furnaces were similar in design and construction to the ten inch furnace. As with the ten inch furnace, the three inch is used to designate the i.d. of the core. Because of the similarity to the ten inch furnace a complete construction schematic is not presented. Figure 11 shows the critical internal dimension and thermocouple position. The dimension of the core was such that 250 milliliter platinum crucibles were used as vessels for crystal growth. The position of the pedestal and crucible were varied throughout the course of the work; position data are included in Table III.

+ Minneapolis Honeywell Co., Route 22, Union, New Jersey.

- + Harold Beck Co., 3640 North Second Street, Philadelphia 40, Penna.
- A Englehard Industries, 113 Astor Street, Newark, New Jersey.

A McDanel Refractories, Beaver Falls, Pennsylvaria.

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#### Pilot Line (Continued)

These furnaces are heated by six Globars wired as three series strings of two bars in parallel across the 208 volt line. (Figure 9) All are saturable core reactor controlled.

The temperature control units for these furnaces are all West Instrument Corporation, Nodel JSBG-3R controllers. These units consist of the temperature controller which is operated on the principle of a beam of light shining on a photocell. The beam is interrupted by a flag as the temperature approaches the set point. The proportional band which drives the magnetic amplifier and the saturable core reactor is determined by the amount of light incident on the photocell. The power input to the furnace is proportional to the photocell output. There is also a cam driven by a synchronous motor for programming. By incorporating various timers and interrupters in the circuits, it is possible to control the rate of change of temperature over a range of one-half degree per hour to fifty degrees centigrade per hour. The limit of control at constant temperature is about plus or minus two degrees centigrade.

While the temperature control is not nearly as sophisticated on the smaller furnaces, the better control is not really necessary. The very fine temperature control referred to for the 10 inch furnaces is necessary for any production type work. The smaller 3 inch inside diameter furnaces are used to obtain some of the process information which is applicable to the larger furnaces. Much of this information can be obtained on equipment which is not nearly as precise as the control equipment used on the larger furnaces. The very fine equipment will undoubtedly yield better crystals. The small furnaces are intended more to yield information than crystals. The process improvements are expected to yield more crystals per run as well as higher quality crystals.

The same kind of statement can be made about the elevators and stirrers for these furnaces. While the requirements are not as great; that is, the elevator is only required to lift a few pounds and the stirrer is required to rotate the same small mass of charge, it was felt that standard elevators and the stirrers with as many interchangeable parts as is feasible would allow the maximum utilization of equipment.

The elevator is simply a convenient method of admitting the sample to the furnace. The stirrer serves to reduce the length of time required to soak and dissolve zinc oxide in the lead fluoride. Stirring, for example, makes the zinc oxide go into solution in one or two hours at 1150°C where it would take several hours at 1250°C without stirring. It might not even be possible to dissolve the material at 1150°C without stirring. Barly work by Nielsen<sup>7</sup>, indicates that zinc oxide should dissolve at 1150°C with no trouble. These temperatures are control thermocouple temperatures while Nielsen referred to

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#### Pilot Line (Continued)

muffle or core temperatures. Even though the smaller furnaces, see Figure 12 for a comparison with the 10 inch furnace, do not require the elevator and stirrer power, it was decided that standardizing these components would be advantageous. For this reason, all the elevators are as nearly identical as furnace dimensions will permit.

#### 2.1.4 Materials and Purity

For the growth of ZnO by the molten salt technique only two chemicais are required, ZnO and PbF<sub>2</sub>, which were purchased from Fisher Scientific Co.+ and Baker and Adamson,  $\leftrightarrow$  respectively. The zinc oxide was the Fisher CERTIFIED ACS Grade which is 99.845 purity. The PbF<sub>2</sub> was B&A Reagent Grade which analyzed as 99.845 PbF<sub>2</sub>.

Cleaning chemicals, acids for the platinum crucibles and NaNO<sub>3</sub> for the crystals were technical grade obtained from various chemical houses.

#### 2.1.5 Weighing and Loading Procedures

The ZnO and PbP<sub>2</sub> powders were carefully weighed on a chemical balance of suitable size. The balance used was different for batches for 3 inch, 6 inch and 10 inch furnaces. The general procedure in loading the crucibles was to pack the ZnO powder on the bottom of the crucible and to pack the PbP<sub>2</sub> on the top. By using this procedure it was feit that as the heavier PbP<sub>2</sub> melted and flowed downward it would help in dissolving the ZnO. A tight fitting cover was then placed on the crucible and the sides of the lid crimped so as to maximize the closure of the crucible.

The platinum crucibles<sup> $\Delta$ </sup> used in this work were of three sizes: 1) 8 inches in diameter by 8 inches high and .050 inch thick walls, 2) 5 1/4 inches in diameter by 5 1/4 inches high and .050 inch thick walls and 3) 3 1/2 inches in diameter by 2 1/2 inches high and .030 inch thick walls.

The usual or typical quantities of  $PbF_2$  and ZnO charge to the three sizes of crucibles are in the same ratio as used by Nielsen and Dearborn<sup>7</sup> and are presented in Table I.

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 Fisher Scientific Co. 1080 Lousons Rd., Union, New Jersey 07083.
Baker & Adamson, General Chemical Division, Allied Chemical Corp. P.O. Box 70, Morristown, New Jersey.

A Baker Platinum Division, Englehard Industries, Newark, New Jersey.

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#### Pilot Line (Continued)

#### TABLE I

Typical Nolten Salt Composition for ZnO Crystal Growth

<b>`</b> •	Wgt ZnO (grams)	Wgt PbFa (Grams)	Moles ZnO	Noles PbF:
3"	44	400	0.54	1.63
6"	322	<b>*29</b> 30	3 <b>. 95</b>	ÍI.95
10"	1320	12000	1620	48,92

In 'foading the ten inch furnace the car was held in the jaws of the mechanical loader and placed on top of the pedestal. Loading of the 6" and 3" furnaces was more easily accomplished nanually with tongs of the proper size and shape to hold the crucible.

#### 2.1.6 Seed Crystal Growth Conditions

Again a general procedure and conditions are presented here in this section; individual experiments wherein various gradients were employed will be described in later sections.

In any of the furnaces used the pedestal with the can resting on top was raised into the preheated furnace. The pedestal position was varied in order to optimize the gradients for the best crystal growth.

The charged crucible was soaked at a temperature, usually 1150 °C for a mimium of two hours while rotating the pedestal. The rotation cycle was as follows: 25 seconds clockwise, 5 seconds stop, 25 seconds counterclockwise, 5 seconds stop and repeat. It was found that without rotation much longer soak periods were required in order to obtain complete dissolution. At the end of the soak period this rotation was stopped and the cool-down began. Depending upon the size of the furnace and specific goal of each run the cooling rate was varied from  $0.5^{\circ}$ C/hour to  $7^{\circ}$ C/hour. In the smaller furnaces, the faster cooling rates of  $3-7^{\circ}$ C/hour were employed since the temperature control was probably limited to  $1-2^{\circ}$ C. In the farge furnace rates down to  $0.5^{\circ}$ C/hour were employed. The cool down period was terminated at 1050°C which meant a cooling period of 24 to 300 hours depending upon the rate employed.

2.1.7 Unloading Operation

At about  $1050^{\circ}$ C -  $1080^{\circ}$ C, depending on the "supposition used, the crucible is rapidly withdrawn and the excess liquid is poured off the crystals.

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#### Pilot Line (Continued)

Preparations prior to the pouring operation are very important. The toxicity of lead fluoride vapors necessitates extreme care in handling. Three people (minimum) are required to pour a large run. One man operates the elevator and directs the movements of the unloading device; he also is responsible for removing the crucible cover. The second man handles the unloading device and does the actual pouring. A third man holds an exhaust snorkel directly above the crucible during the entire operation. The second and third men are equipped with appropriate gas masks (Model H, plus canister EA 81524, manufactured by Mine Safety Appliance Co.<sup>+</sup>). Also, during the entire pouring period, a high volume roof exhaust fan is in operation.

The actual pouring operation should be accompliated in less than 10 minutes to prevent the liquid from freezing. The sequence of events consists of the following:

a. Prepare equipment, turn on exhaust fans, and put on gas masks, as described above.

b. Lower pedestal and grab crucible with jaws of unloading device (1 - 2 minutes).

c. Run pouring device down track and remove crucible cover (1/2 - 1 minute).

d. Pivot unloading device and slowly pour liquid into sand box or water cooled metal container (4-5 minutes).

e. If the crystals are floating, they should be prevented from escaping with the liquid. This is normally done by holding a metal rod across the rim of the crucible near the pouring area.

With the smaller crucibles the same health safety precautions were taken with the use of gas masks, and venting of the fumes. The flux pouring was essentially the same except that manually operated forceps were used to remove the crucibles and pour the flux.

2.1.8 Crystal Separation and Cleaning

After the platinum crucible has cooled to room temperature, it is gently tapped with a plastic hammer to loosen the crystals which are attached to the wall and floor.

The usual flux removal technique for cleaning crystals employ one or more acids. Zinc oxide, though a refractory material is quite readily attacked by acids and so a different procedure had to be

+ Mine Safety Appliance Co., 201 North Braddock Avenue, Pittsburgh, Pennsylvania
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developed.. Simple mechanical removal of the flux by grinding, scraping etc. was not possible because of fragility of the thin 280 plates.

A somewhat different approach was required to clean the ZnO crystals of any adhering  $PbF_2$  flux. The procedure which was developed was as follows:

1. The ZnO plates with adhering flux were placed in a stainless steel screen baskst. (2" dismeter)

2. This bester The ther into a 250cc platinum crucible which contains molten NaNO<sub>2</sub> (mp 307°C).

3. After several minutes in molton MaNO3, the basket was slowly withdrawn.

4. After cooling is air to room temperature the basket with the plates was placed in a beaker which was being flooded with hot water.

5. The cleaned plates were then washed with distilled water and air dried.

This procedure was quite satisfactory. The molten NaNO<sub>3</sub> did not attack the ZnO crystal but did react with adhering  $PbF_2$  to form water soluble  $Pb(NO_3)_2$  and the just slightly less soluble NaP. The combination of molten NaNO<sub>3</sub> followed by hot water proved to be a satisfactory approach to cleaning the molten salt ZnO plates.

2.2 Hydrotherma

2.2.1 Laboratory Facility

A pilot line for the hydrothermal growth of large ZnO crystals was designed and assembled. A 20-feet long x 4-feet wide x 4-feet deep pit with reinforced concrete walls was constructed in the laboratory to contain the autoclaves and furnaces when in operation. This pit provides personnel protection against scalding or fragmentation which could result from equipment malfunction. The pit contains six furnaces, four large ones for the large A-286 autoclaves and two for the small Waspalloy vessels, and a saturable core reactor for each furnace. At one end of the pit is located a sump and automatic pump in the event of ground water seepage into the pit. This sump area of the pit is also used for cleaning and cooling of the autoclaves. This equipment was obtained under Air Force Facilities Contract AF33(957)-12307.

The furnace heights are adjusted so that the tops of the autoclaves are just floor level. The pit area is covered by removable steel grill sections. Mounted on the nearest wall are the temperature controllers and programmers for the hydrothermal furnaces.

A one-thousand pound capacity travelling hoist is mounted overhead so that the autoclaves may be readily moved.

The laboratory is also provided with chemical work benches for silver can preparation, loading and storage. A fume hood and large overhead exhaust fan supply ventilation for protection against chemical vapors.

A floor plan of the laboratory showing its hydrothermai and molten salt facility is shown in Figure 2. Figure 13 is a photograph of the pit area showing the larger furnaces and autoclaves.

### 2.2.2 Hydrothermal Crystal Growth Autoclaves

In order to grow crystals weighing 150 grams or more as specified in the contract, it was necessary to purchase vessels of sufficient cavity size to contain such crystals. The cavity size was large enough so that crystals at least two inches in width could be grown in suitable silver cans.

Of the available materials for autoclave construction, that of maximum pressure and temperature (P-T) limits was chosen since, at the time of purchase, these variables for crystal growth were not known. It was also necessary to select a seal design capable or containing the high pressure temperature conditions. As a result of these criteria, the vessel as shown in Figure 14 was chosen, - the material of construction being A-286 whose pressure-temperature ratings are 30,000 psi and  $590^{\circ}$ C for 10,000-hour life.

The autoclaves were manufactured by Autoclave Engineers, Inc., Erie, Pennsylvania, who had developed what is called a "Modified Bridgman" seal. This seal is that used by Western Electric and others for quartz manufacture and believed to be the best workable, high temperature, high pressure seal. This seal is described as "selfenergizing" since it relies upon the internal pressure developed by the fluid under growth conditions to provide for sealing force. The vessel is initially sealed by the main nut's downward thrust on the seal ring and then upward thrust on the piston by means of the set screws in the lock nut. Opposite screws are tightened in turn by means of a torque wrench to 10 ft. lbs. each. This sealing initially causes the seal ring to make line contacts with the autoclave body and plunger. As the internal pressure develops, the plunger is thrust upward causing the seal ring to deform elastically and produce surface contacts. This self-energized seal provides better sealing as the internal pressure increases.

During the early part of the program autoclave failure developed as a serious problem. One of the first four autoclaves failed because of a flaw in the original ingot from which it had been fabricated. The failure of the remaining vessels was caused by stress corrosion cracking.



Figure 13 - Pit Area, Furnaces and Autoclaves

Some form of stress and the presence of a corrosive atmosphere are the two elements necessary for the initiation of this particular type of failure. In the case of hydrothermal autoclaves used for crystal growth, the force is provided by the working pressure and the corresive atmosphere is the result of occasional leaks in the noble metal (silver) container used to hold the caustic solutions. The three causes of leaks in the silver cans have been: 1) corrosion of the silver, 2) improper pressure balance leading to can rupture, and 3) faulty welding.

Experience has shown that even a limited exposure is sufficient to instigate this corrosive force and that failure can occur at some later date. A change in autoclave design was suggested to Autoclave Engineers to aid in extending the life of a vessel by preventing stress corrosion cracking from occurring too extensively. In order to do this, it was suggested that the bottom of the cavity be changed from conical to hemispherical. The conically machined tip was thought to be a place of high stress and particularly subject to attack by base. In the five vessels which failed on Contract AF33(657)-8795, the failure in each case was at the center of the bottom of the vessel.

This conical tip was also questioned in view of the rather thin wall at the bottom of the vessels. It was suggested that perhaps a thicker bottom (increased by one inch) would add extra strength to counteract any applied stress. Our experience with two Waspalloy autoclaves with 2.5 inch thick bottoms had been favorable in view of their long life even when subjected to basic solutions at higher pressures and temperatures. There were some differences in conditions to which the two types of vessels had been subjected. The Waspalloy vessels were used for ruby growth where the solvent is  $K_2CO_3$  solutions and the working conditions of 25,000 psi and 525°C; whereas, correspondingly, the A-286 vessels for ZnO growth were used with KOH solutions at 7,500 psi and 300°C.

Autoclave Engineers concurred that these modifications certainly could not add to the problem and could probably help. Only slight addition in cost was necessary to cover production of the thicker hemispherical end, Figure 15. Two such vessels were purchased and used with satisfaction during the balance of the pgogram. This design change has now been incorporated by Autoclave Engineers in all their standard crystal growth vessels.

One other difficulty is noted here since it involved an unpredicted behavior of the seal. While the seal ring does deform elastically at lower pressures and temperatures, it was found that plastic deformation occurred at higher temperatures and pressures (500°C and 20,000 psi) which were still well below the maximum temperature and pressure for which the vessels were rated. This deformation does not interfere with the vessel closure but does necessitate machining the seal ring after each use and careful preparation of all







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scaling surfaces prior to use. Machining, lapping tools, and techniques to produce reliable scaling of the autoclaves are discussed in section 2.2.8.

### 2.2.3 Silver Cans

Noble metal containers or cans are used in order to prevent contact of the autoclave body with the basic solution used in ZnO crystal growth. This is necessary since the solution would corrosively attack the autoclave metals under hydrothermal conditions. The containers were made of seamless, fine silver tubing and flat circles of the same material. The baffle and seed rack were also made of fine silver. The first silver cans used were 2 inches in diameter by 24 inches long.

The design of the silver can was changed to a completely sealed system in the course of the program for two reasons: 1) in order to contain the large crystals and 2) it became apparent that better pressure balance could be achieved with a larger can. (See section 2.2.4). As the crystals increased in size it was noted that the crystal growth at the edges near the silver can was being affected by a restriction in flow of the fluid. Therefore it was desirable to make the silver can as large as possible. The second can design is shown in Figure 16. The silver materials for the fabrication of the cans were purchased from Handy and Harmon Co.+ in the form of flats, tubing and wire. The dimensions of the cans, rack, baffle etc. are shown in Figure 17. After normal machining and cutting to the dimensions specified in Figure 17 the can and internal rack were fused together without a fluxing agent using a Miller Welder, Model 330 AP, in an atmosphere of argon gas. The final sealing of the can after filling with seeds, nutrient and fluid is described in section 2.2.10.

### 2.2.4 Large Can Technique

At the onset of this Contract, it had been the practice, when using noble metal cans, to adjust the volume of the can (internal volume) to be nearly equal to the remaining autoclave volume (external volume). The problem of using noble metal cans rests in the different equations of state for water and hydroxide or carbonate solutions. Since the equations are different, water and any aqueous basic solutions of the same percent fill and at the same temperature would generate different pressures. It has been found for all of the

+ Handy and Harmon Co., New York, N.Y.
++ Miller Co., Appleton, Wisconsin.





common hydrothermal solvents that the pressure generated by a solution is less than that of pure water.

As a result of these differences, an adjustment of the fills (internal to external) must be made so that at temperatures the same force is exerted by the base and water. Any grave urbalance of fill conditions would lead to severe compressive or extinsive damage to the can which could lead to development of a leak. Because of the pressure-temperature behavior of these fluids, there is only one pressure and temperature condition at which there will be perfect pressure balance for any set of fills. See Figure 18.

The void external volume is obtained by measuring the volume of the autoclave when empty and subtracting the peometrically calculated volume of the can. The percent of this volume to be filled with water is defined as the external fill. The internal fill is similarly defined. It is obtained by calculating the volume of an empty silver can based on its geometry. From this value are subtracted the volume of the seed rack and baffle (calculated from geometrical forms) and the volume of seeds and nutrient (calculated from weights and density of ZnO). This value is then the void volume of the can and the percent to which it is filled with KOH solution is defined as the internal fill.

The figure is a somewhat exaggerated pressure-temperature diagram for water and a basic solution capable of exerting the same pressures at one temperature only. If one follows along the lines as if the vessels were warming; i.e., the temperature is increased. it will be noted that below the point (F,f) the external or water pressure is greater than the internal or base pressure and chus the can is under compression. At (P,T) the pressures are balanced so that the can is subjected to neither compressive nor expansive forces. Higher temperatures again cause an imbalance in pressure but now the can must expand. Even if the equations of state were known, the can would be subject to compression at the run warm-up and cool-down; however, the fills for the pressure-temperature balance point might be calculated rather than arrived at by experimental observation. Two other points are worth noting at this time.

In addition to not knowing the equalion of state for the basic solution, any such equation would not be quite correct since at operating conditions the solutions contain 5 - 10 percent ZnO, and so a further perturbation of the equation would be necessary. Second, the treatment of this subject has been presented as though the systems were isothermal. For crystal growth, this is certainly not the case and some averaging of the equations would be necessary to apply the data.

The problems of severely working the silver can and matching pressures can be greatly alleviated by the use of a can which nearly fills the autoclave cavity. This technique was developed during



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the Contract when it was thought that the cans might sometimes be completely crushed when under growth conditions.

By using the large can neither of these conditions can occur as readily. For example, if the internal fill is larger than it should be by some reasonable value, the can will be under compression (hring the warm-up. When the crossover point is reached, and the temperature continues to increase, then the can undergoes expansion. Since the void volume is so small now a small percent change of the can's dimensions caused by expansion leads to a large percent decrease in the void volume. The large decrease in void volume also has the effect of producing a correspondingly large increase in pressure of lo external volume and hence a restoration force. In other words. sall expansion of the can's dimensions leads to a relatively lar-.crease in the external volume effectively raising its percent fil. urthermore. due to the closeness of the fit, a bulge cannot occur in  $\alpha \neq 0$  one region and the expansion is spread out over the estire length of the can-

In the case of the internal fill being lower than it should, the can again will be under compression during the warm-up. When the operating temperature conditions are reached, the can is still under compression; however, the effect is now less since the small compression of the can leads to a large increase in the external volume. This increase in external solume essentially leads to a reduction of the fill and reacts to lower the compressive force.

With fairly accurate filling, only slight movement of the walls is required to produce balance. Thus, the gauge pressure is more nearly the internal pressure and the external fill acts only as a transmitting fluid.

For the low pressure work the internal fills were obtained from the data of Laudise et al $^8$  and the external fill from Kennedy's Tables. Fills for the high pressure work were acquired by extrapolation of the compressive fill data.

### 2.2.5 Hydrothermal Furnaces

The furnaces used to heat the autoclaves are shown in Figure 19. The furnaces, originally designed and built by Research & Development Products, Inc., New Market, New Jersey, consist of clam shell type of heater sections constructed of Nichrome resistance wire cemented in a grooved ceramic, insulating wool materials and outer metal shells.

Since the bottom section of the autoclave must be the hotter section, it was found that the bottom should receive the greatest power and only slight or auxiliary heating was necessary in order to level out or adjust the proper temperature difference between sections.



sfter a number of failures in the bottom section, this section was redesigned so that the bottom of the vessel rested on an electric range heater. The main heat was applied to the bottom of the vessel by this electric range element. Figure 20. Setter contact and more even heat distribution was achieved by placing an 8"  $\times$  8"  $\times$  1/2" stainless steel plate over this heater.

It was found that the amount of power for a fixed set of conditions carried somewhat for each combination of autoclave vessel, furnace and controller.

### 2.2.6 Temperature Control

The power to the electric range surface heating element or hot plate element is controlled by a saturable core reactor through a West Programmer Controller; a control thermocouple is comented to the firebrick immediately below the hot plate element. The class shell heater is also controlled by the West instrument by means of a manually set ratio for power distribution to each furnace element. This distribution of power is accomplished by the S-92 option of the West JSBG- 3R Program Controller, which allows the output from one temperature controller to drive-up to three saturable reactors. In this case only two reactors are used. A schematic of the control system and furnace is shown in Figure 21. The control thermocouple supplies the input signal for the operation of the controller and driver.

The temperatures along the body of the autoclave were monitored during the course of the run by means of four thermocouples located at  $1 \frac{1}{2}$ .  $9 \frac{1}{2}$ , 21" and 34" from the bottom of the vessel. The temperature was measured using a Leeds and Northrup Millivolt Potentioneter, Catalogue No. 8690.<sup>+</sup>

The functions of the various components shown in Figure 21 are discussed below. A & B are components of a Model JSBG-3R Temperature Controller manufactured by West Instrument Corporation, Chicago, Illinois.

A -The instument uses a galvanometer detector powered directly by the thermocouple. An opaque "flag" attached to the galvanometer pointer is positioned so that it can diminish the light reaching the photocell. The photocell current is the input to a magnetic amplifier, rectifier combination which has a d.c. output propportional to the illuminated area of the photocell.

+ Leeds and Northrup, Philadelphia, Pennsylvania.

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Figure 20 - Electric Range Element



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Figure 21 - Schematic of the Control System and Furnace

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<u>B</u> - The set point or control temperature is adjusted by moving the light-photocell unit either up-scale or down-scale causing the temperature indicator to "chase" the photocell. An aluminum can driven by a synchronous motor is mechanically connected to the lightphotocell unit. The shape of the can controls the position of the lightphotocell unit and thus the temperature.

<u>C</u> - The d.c. output of A is further amplified to a level sufficient to drive three saturable reactors. The reactor driver with auxiliary driver is manufactured by West Instrument Corporation.

<u>D</u>- The d.c. output from C is divided and matched to three loads, two reactors and a dummy load resistor. Individual adjustment of the fraction of the d.c. power reaching each reactor is provided for This allows the relative power output of either reactor to be adjusted. The unit is an S-92 feature, manufactured by West Instrument Corporation.

<u>E</u> - The saturable reactors are rated for five KVA, 220 volt. The a-c current passing through the reactor is a direct function of  $\Rightarrow$ -c control current. The reactors were manufactured by West Instrument Corporation.

F - Directly connected to the furnace units are two, 2 KVA 220 volt variable auto-transformers, manufactured by Superior Blectric Corporation, Bristol, Connecticut. The auto-transformers permit the adjustment of temperature differences between the top and middle cylindrical heater by limiting the power in the middle heater. In similar fashion the hot plates and bottom cylindrical heaters can be adjusted.

### 2.2.7 Pressure Measurement

Pressure in the system is obtained by direct reading of Bourdon type gauges connected directly to the internal cavity of the autoclave. Since the walls of the silver cans are deformed under only slight pressure, the gauge pressure is a fairly accurate measure of the internal pressure of the can. Ashcroft Maxisafe<sup>+</sup> gauges (Autoclave Engineers, Inc., authorized vendor) with Monel Bourdon tubes and F250-C fittings were used.

2.2.8 Equipment Developed During Contract

Use of the autoclaves and associate equipment required the development of some additional tools whose necessity had not been anticipated.

+ Autoclave Engineers, Erie, Pennsylvania.

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### 2.2.8.1 Autoclave Opener

Closure is achieved with manual force only, according to the technique described in Section 2.2.2. Operation of the autoclaves proved that the manufacturer's recommended technique and tools supplied for loosening the main nut after a run were far from adequate. In order to unscrew the main nut, and in some cases provide the only possible technique for removing it, a new anviltype tool was developed (Figure 22). This tool was constructed so that it could easily be clamped onto the main nut by means of two bolts. When in place, two steel pins in the tool fitted into two opposing holes on the side of the main nut. The pins in these holes allowed for efficient transmission of the applied torque. For opening the autoclave, this torque is provided by striking the arms of the anvil openers with ten-pound hammers. No pressure-temperature or leak condition produced sealing of the vessel which could not be opened by this tool.

### 2.2.8.2 Can Extractor

Because of improper pressure balance or slow le.ks in the entire system, there would occur in some cases a puffing up of the silver can. Due to the proximity of the autoclave walls, this expansion could not proceed too far. The movement of the can s wall could be stopped by the autoclave walls. As a result of this large expansive force, the silver can walls would be forced against the autoclave making removal of the can extremely difficult.

While this situation was true of the small can and vessel, it is even a greater problem in larger cans (3 inch diameter). In order to remove the cans after a lun, an extractor (Figure 23) was designed and constructed which could be used with both vessel sizes. For the smaller can, a large screw was threaded into the top cap to provide a clasping handle. The cap of the larger can was provided with a large nut for easy removal. After clasping this handle in either case, the can is removed by driving the threaded rod with an electric drill. This instrument has removed cans which appeared to be impossible to remove manually.

2.2 8.3 Sear Area Lapping Tool and Polishing Tool

In order to regenerate and polish the sealing surface of the autoclave properly, it was necessary to design and develop two tools, - the final models of each are shown in Figures 24 and 25.

The lapping tool is made so as to generate a surface of the proper sealing angle  $(7^{\circ})$  whose bore was concentric with that of the threads. This particular alignment was found to be necessary since the bore used for the threads and that of the autoclave body are not necessarily uniaxial. Deviation from this geometric -43-







Figure 24 - Seal & ca Lapping Tool

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configuration leads to seal leaks. The Lapping section of the tool is made of cast iron; the surface of the Lap is regenerated periodically by milling. The guide in the body of the tool is made or aluminum and is fitted for one vessel specifically and used only for that vessel thereafter.

A polishing tool was also developed to be used after the seal surface had been ground with the lapping tool. The mirror polish produced by this tool was found to be essential in order to seal the autoclaves for use at combinations of high pressuretemperature conditions (>500 °C - 20,000 psi). In this case, after the autoclave has been suitably ground with the lapping tool, the polisher is placed in the seal area and driven at high speed by an electric drill. With experience, mirror finishes are easily attained in a matter of 2 to 3 minutes. No. 320 aluminum oxide abrasive is suspended in an oil slurry and used for both the lap and polisher.

### 2.2.9 Operating Procedure

### 2.2.9.1 Preparation of Large Crystal Growth Autoclaves

After each run in the autoclaves, it was neccessary not only to clean thoroughly the vessel but also to renew the sealing surfaces and angles. The vessel cavity was scrubbed with a large diameter ( $\sim 3$  inch) brush and liquid detergent; it was then rinsed by flushing with tap water and dried by a stream of compressed air. During each run the seal parts underwent plastic deformation to a greater or lesser extent resulting in permanent dimensional changes in all three seal parts. The ring, cover and autoclave seal areas had to be returned to original dimensions and surface finish each time the autoclave was used. If this was not done the seal became unreliable. The preparation of each part is discussed in turn below.

2.2.9.1.1 Seal Ring

An expanding mandrel shown in Figure 26 was used to hold the seal ring during the remachining of the sealing surfaces A modified vernier caliper shown in Figure 27 was used to measure the critical dimension which was the minor outside diameter of the taper. The ring was machined to the angles and dimensions shown in Figure 28. The angles are slightly different from those prescribed by the manufacturer (Figure 14.) but only with the specifications depicted in Figure 28 could reliable sealing be attained. Both inner and outer angular surfaces were then polished using No. 180 Al<sub>2</sub>O<sub>3</sub> U BOND METAL CLOTH from Sandpaper Inc., Rockland, Massachusetts.

### 2.2.9.1.2 Cover

The sealing surface of the cover was remachined to the angle shown in Figure 14 . Polishing of the surface was done using the same No. 180 cloth as above.



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Figure 27 - Seal Ring Caliper

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Figure 28 - Seal Ring



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### 2.2.4 1.3 Autociave Seal Area

The seal area of the autoclave was lapped with a mixture of 2 volumes of SAB 20 machine oil plus 1 volume of NCRTON No. 320 aluminum oxide abrasive using the lapping tool shown in Figure 24. Lapping was continued until all traces of former seal marks were removed. The seal area was then polished using WBT-ORDRY TRI-M-ITE PAPER No. 320 SILICON CARBIDE (3M Co., St. Paul, Minnesota) and SAE 20 machine oil. The paper was fixed to the polishing fixture shown in Figure 25. An electric drill controlled by a variable transformer drove the polishing fixture at 200 to 300 RPM. A good polish was required, i.e. no visible flaws with the unaided eye.

All parts were scrubbed with detergent<sup>+</sup> and hot water to remove any residual grit. Prior to assembly all surfaces were wiped with Kimberly-Clark type 900-S Kimwipes saturated with acetone. The vessel was then sealed according to the manufacturer's directions.

### 2.2.10 Nutrient Preparation

ZnO nutrient was prepared from commercially available ZnO powder. Fisher<sup>++</sup> CERTIFIED ACS grade was used. Depending upon the quantity of nutrient required and the availability of a sintering furnace two sizes of platinum crucibles were employed, either a 250 ml for the three inch Turnace or the 5 1/4" x 5 1/4" can for the six inch furnace. The ZnO powder was packed into the can and the can placed in the furnace operating at 1100 - 1200°C. After 2-3 hours at temperature the can was removed. The result of this operation was a cylinder of sintered ZnO. This cylinder was then crushed in a silver metal tube; 1/4 inch to 1/2 inch pieces were the most desirable nutrient size.

### 2.2.11 Solution Preparation

The solution used for the growth of crystals was 6 molal and was prepared by adding 1009.8 grams of Fisher CERTIFIED ACS grade KOH to 3000 grams of water. Typically the solution was also 0.1 m with respect to LiOH which was prepared by adding 4.19 grams of Fisher CERTIFIED ACS grade LiOH+H<sub>2</sub>O to the 3000 grams of water.

### 2.2.12 Seed Preparation

Zinc oxide seeds for the final and most successful portion of the program were produced from hydrothermally grown crystals. The crystals were mounted and cut perpendicular to the <0001> axis

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<sup>+</sup> Lux Liquid, Lever Brothers, New York, New York.

<sup>++</sup> Fisher Scientific Co., 1080 Lousons Ed., Union, New Jersey. Lot No. 745324 or 714125.

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### Filst Line (Continued)

yield large area plate whose thicknesses were 50 to 100 mils. The plates were then cleaned with methanol and a small hole was drilled near one edge of the seed. A 20 mil wire was placed in the hole and the seeds suspended on a silver ring for etching. The ring with the seeds were submerged in hot 10 molal Na(H ( $\sim 90^{\circ}$ C) for 5 minutes. The ring and seeds were then flushed in flowing tap water, rinsed in deionized water, and finally air dried, ready for attachment to the seed rack.

### 2.2.13 Preparation of Silver Can-loading of Autoclaves

Just prior to loading the cans for a run, the silver pieces were cleaned of grease and oil with detergent, washed with concentrated HCl, thorougly rinsed with deionized water and then allowed to dry.

Most hydrothermal ZnO crystal growth runs were in excess of one month duration. This provided ample time given even a very small leak in the silver can to cause serious damage to the autoclave. In fact, an autoclave could easily be rendered useless in a single run. Testing for leaks in the system before use was a prime requirement for successful operation of a crystal growth system.

During construction of the cass all welds in subassemblies were subjected to a dye-penetrant test<sup>+</sup> and any suspicious areas were welded and tested again. The seeds were attached to the seed rack with 20 mil fine silver wire and the nutrient and zinc metal were placed in the bottom of the can. The seed rack and baffle subassembly was then welded to the can body. Any pressure within the can generated by the heat of welding was relieved through the twin vent tubes in the cover. The cover to body weld was then dye-checked and rewelded if necessary.

One hundred milliliters of <u>deicnized</u> inter placed in the can through one of the vent tubes. The ends of both vent tubes were then flattened with heavy pliers and the tips fused, thus sealing the can.

The can was then weighed to  $\pm 1/2$  gram. Final leak testing was done by heating the can to 110 to 120°C with a Briskeat<sup>++</sup> type D heating tape operating at 70 to 80 volts from a variable transformer. The can was kept hot for 15 to 16 hours and then weighed again. If there had been no loss of weight the ends of the vent tubes were cut and the test water boiled out. When all the water was removed, the KOH solvent was introduced through one of the tubes which were then flattened and sealed.

<sup>+</sup> Spotcheck, Penetrant Type SKL-HF, Sptocheck Developer Type SKD-NF, Magnaflux Corporation, Chicago, Illinois.

<sup>++</sup> Scientific Glass Co., Bloomfield, New Jersey.

### Philip Lipe Continued:

The can was then placed in the autoclave, along with the appropriate external fill of deconized water. The vessel was closed, the pressure gauge attached and the vessel was placed in the furnace ready for operation.

### 2.2.14 Harm-up

Two different warm-up schemes were used in the course of this work: (a) programmed and (b) "as fact as possible." The programmed procedure was used only in the early part of this work when the operating pressure was low. In this case, the vessel was heated at a constant rate to operating conditions over 24, 48 or 96 hours by using the temperature programmer modification on the West Controller.

During the warm-up a low gradient was maintained between the bottom and top sections of the autoclave. Since the seeds were so thin in the early part of the program it was found that by using the slow warm-up with a low temperature gradient that most or all of the seeds would be dissolved before arriving at growth conditions.

Drastic seed dissolution was prevented by heating the vessel to operating conditions "as fast as possible", with a high temperature gradient. This was accomplished by having the power inputs on the controller fixed at their ultimate position for operation and then switching on the controller.

Operating conditions were approached within 2-3 hours with an additional 3-4 hours required for the entire assembly of furnace, vessel, etc. to attain thermal steady state. This procedure prevented seed dissolution, and was used for the major part of the program.

### 2.2.15 Shut-down

At the end of the run, the power was switched off and the autoclave was air cooled; when zero gauge pressure was indicated, cold water was then passed over the vessel until it reached room temperature. The vessel was opened with the main nut released by the opener (Figure 22). The silver can was removed manually from the autoclave or with the extractor (Figure 23). The cap was sawed off and the ladder removed from the can. The crystals were removed from the holder by cutting the wire and then thoroughly rinsed in water until all the base was washed away. The crystals were then allowed to air dry prior to weighing and measuring the thickness with a micrometer.

### 3.0 CRYSTAL GROWTH

### 3.1 Molten Salt

### 3.1.1 Background for Program

It had been demonstrated by Nielson and Dearborn at Bell Telephone Laboratory that fairly large (1-2 inch) high quality plates of ZnO could be grown using the molten salt technique. After joining Airtron Dr. Nielsen and Mr. G. Townrend continued growing zinc oxide plates by the same method. There was no apparent difficulty in using this technique to grow ZnO crystals which would provide seeds for the hydrothermal crystal growth.

The initial success did not continue and it became more and more difficult to obtain the plates of size, quality and thickness previously observed using the same growth parameters. The difficulties were manifested by the decreasing frequency of successful runs, crystals of smaller area, and a large decrease in plate thickness.

Attempting to cope with the degeneration of the system a course was set upon to investigate thermal gradient effects, furnace effects and batch size effects.

This difficulty in producing plates by the molten salt approach was also noted by Laudise.<sup>11</sup> Both laboratories then approached the seed problem by using hydrothermal crystals as a source of seed plates.

### 3.1.2 Crystal Growth Experimente

Initially the work began by simply duplicating the composition and procedures used by Nielsen and coworkers. This work was quite successful and large plates were easily grown (Figures 29 and 30). During this first phase both three inch and six inch furnaces were used for crystal growth.

At that time not all of the furnaces in the pilot line were equipped with rotating pedestals. It was found that without rotation it was not possible to dissolve ZnO at 1150°C, even with a twenty four hour soak period. On the other hand with rotation only a two hour soak period was necessary to dissolve all the material

In order to optimize crystal quality and yield, a series of experiments was begun in which the pedestal position and therefore crucible was varied in the furnace. The purpose in changing the position of the pedestal was to alter the thermal gradients in the melt. By so doing it was possible to have either the top or bottom of the melt in the hottest part of the furnace. The objectives were to see if the number of nucleation sites could be reduced so that the crystal once nucleated could be induced to increase in basal area and thickness, and to eliminate dendritic growth. The other important







### Crystal Growth (Continued)

growth variables a g, cooling rate were also varied in order to accommplish the same objectives.

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The data for the runs is, this period are presented in Tables II and UII.

The conditions used where the best plate was obtained are as follows:

The starting mixture was composed of 25 mole percent ZnO and 75 mole percent  $7bF_2$ . The container widh a 5 1/4" x 5 1/4" crucible with cover which was run in the 6 inc. furnace. The pedestal position was such that the bottom of the platinum can was just above the lower portion of the furnace hot zone. In terms of gradients this would mean that the temperature at the surface of the melt was higher than any other part of the flux. The contents of the crucible wave scaked at 1150°C for two hours with stirring. The timing was stopped and the furnace cooled at 1°C per hour. At 1050°C the crucible was removed and the solution poured into a sand bath.

With the continued decrease in plate yield, thickness and quality, more variation of gradients, batch size, melt composition and soak temperatures were attempted. No significant improvement was obtained by any of these changes, Table IV.

### 3.1.3 Controlled Nucleation and Crystal Growth

As the  $ZnO = PbF_2$  system continued to degenerate considering the size quality and thickness of the plates, more thought was devoted to how to control the factors involved in rucleation and growth of ZnO plates. A program was begun to see \_f these objectives could be accomplished in a molten salt system.

In addition to growing platelets of ZnO which float on the surface of the melt, it had been observed that in some runs the platelets also appeared to grow in a vertical position rather than horizontally. The presence of the vertical plates, Figure 31, supports the analysis that the heat flows in the vertical furnaces in such a manner as to result in vertical gradients. In order to control mucleation and subsequent crystal growth, it is necessary to control not only the amount of the gradient, but also the direction of the gradient. While large plates have been grown in some cases in vertical gradients, originally large plates were grown in horizontal furnaces which probably had lateral gradients.

### 3.1.3.1 Vertical Gradient Method

A vertical furnace that is cylindrical in construction and further has radial symmetry about its axis, both in construction materials and in heat dissipation, has only one significant gradient, which is in the vertical direction.

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# Molten Salt Crystal Growth Runs

Position +8	Temp.	Soak Time (hrm) A	Cooling Rate (C/hr)	Removal Temp. (°C)	Comments
D F	1205	4	14.0	850	Polycrystalline plate, ZnO not complete- ly dissolved - dendritic growth.
\$	1220	4	8.3	875	Flawed plate ZnO not completely dis- solved, dendritic growth.
L+	1330	16	8.3	850	Tiered plates attached by flux, den- dritic growth.
ş	1300	16	5.6	950	Polycry <b>stalline</b> plate.
4	1250	15	ŝ	1000	Some good areas, much polycrystalling.
7	1200	4	6	1025	Much undissolved.
<b>6</b> +	1180	Ċ,	10	1050	Parallel plates cracked.
<b>6</b>	1100	a	6.7	1000	Parallel plates, much flux inclusion
1+	1150	*	4.8	1025	Much strain cracking.
o	0511	4	2.4	1025	Large area excellent, age Ficure t
<b></b> 1	1150	ŝ	0.5	1055	Large plate with heavy inclusions
1+	1150	8	2.0	970	Many plates, wall nucleation.
1+	0611	Ø	<b>3</b> .0	1025	Mall nucleation number of plates de- veloped.

K Crucible Position column numbers indicate position of the center of the can relative to the center of the furnace in inches.

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### TABLE III

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ALC: NO.

## Melten Salt Crystal Growth Runs

10-13	10-13	10-11	10-10	10-9	10-8	10-7	10-4	10-5	10-4	Run
+ 2	* 20	1	*1	• •	-1	o	+1"	+ N	+ N 2	Crucible Position
1150	1150	1160	1150	1150	1150	1150	1150	1150	1150	Soak
u	u	u	La	u	u	U.	U.	u,	, <b>u</b>	Soak Time (hrg.)
u	<b>ئى</b> ا	نیة	w	1.0	0.5	0.5	0.5	0,5	<b>b</b> ) 5	Cooling Rate °C/hr.
1045	1025	1050	<b>0</b> 601	1025	1050	1000	990 0	1025	1000	Pour Temp (°C)
80-85	80-85	75-80	75-80	70-75	60-65	70-75	75-80	80-85	80-85	AT (°C)
10	u	8	15	8	8	3 9	10	8 6	3	Plates
8	95	8	85	8	001	100	8	100	70	5 Dendrite
Flux included, no usable plates.	Almost no plates.	Thin plates some good areas.	Plates have flux included den- drites attached.	Some plates, no flux included, dendrites,	Dendrítes.	No plates, den- drites.	Some small plates, no flux included, mostly dendrites.	No plates, den- dritic.	Some plates heavily flux included, mostly dendtries.	
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Coma en t	Flux included, some good areas.	Flux included.	Some good areas 1 - 2 cm <sup>2</sup> .	Some good areas.	Good plates, thin.	Plate with dend- rites.	Lost cover, dendrites.	Plate with sume dendrates.	Last cover, mostly dendrites.	Dundrites.	Plate with some dendrites.	Thin plates, some dendrites.	Lust cover.
K Lendritea	65	75	50	25	œ	8	100	8	<b>56</b>	100	70	05	100
A Plates	35	25	8	75	70	4	\$ \$	R	Ś	a	8	S	1
AT (°C)	70-75	75-80	70-75	70-75	30	8	8 8	35	R	15	2	8	8
Pour Temp.	1055	1035	1040	1050	1025	1025	1000	066	1025	1010	1030	1030	0501
cooling Rate °C/hr.	'n	S	'n	7	1.5	0.5	1.0	1.0	1.0	1.0	1.0	3.0	3.0
Soak Time (hrg. )	'n	'n	÷1	n	•	•	•	•	•	•	•	87	•
Soak Tenp.	1150	1160	1160	1160	1150	1160	1150	1155	1130	1160	1150	0911	1155
Trucible <sup>®</sup> Seition	E/T T+	+1	+1 1/3	e/1 1+	6+	<b>67</b>	÷	a +	1+	0	1+	<b>1</b>	1+
Eun 1	10-14	10-15	10-16	10-17	<b>6 -</b> E .	6 1 1	<b>.</b>	in T	9-6	3-7	<b>9 - 6</b>	<b>9-0</b>	3-10

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3-23	3-22	3-21	3-20	3-19	3-18	3-17	3-16	<b>3-15</b>	3-14	<b>3-13</b>	3-12	3-11	R n
+1 1/2	+1 1/3	<b>6 4</b>	<b>£</b>	o	o	+1	+1	*1	*1	*	+2	+1	Crucible <sup>®</sup> Position
1100	1170	1150	1150	1170	1170	1165	1160	1170	1170	1160	1160	1160	Soak Temp.
•	•		•	•	•	•	•	•	•	•	•	•	Soak Time (hrs.)
Ţ	7	U	U	<b>U</b>	u	u	U.		ນ • <b>5</b>	<b>a</b> .	نيا	2.0	Cooling Rate °C/hr.
1040	1025	1035	1030	1025	1040	1035	10 <b>50</b>	1025	1000	975	1010	1020	Pour Temp. (°C)
25	25	35	35	15	IJ	25	24	20	8	OE	30	20	AT (°C)
8	8ĉ	\$	ð	•0	£	8	75	ŝ	ŝ	60	8	\$ 8	% Plates
. 10	8	8	8	8	8	20	25	8	8	\$	\$	100	5 Dendrite
Thin plates, 1 - 2 cm <sup>2</sup> good area.	Thin plates, some dendrites.	Mostly dendrites.	Multiple nucleation cool walls.	Mostly dendrites.	Mostly dendrites.	Thin plates.	Thin plates mult- iple nucleation.	Dendrites with small plates	Dendrites with many small plates.	Small plates dendrites.	Many small plates.	Lost cover,	Ccanents

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		This plates.	Good but thin	1~2 cm <sup>2</sup> good area. Thin plates, al-	Thin - multiple nucleation.	Programmer failed.	Thin plates, 1-2 cm2 good area.	This states	Thin plate.	Thin plates, 1-2 cm good	Mostly dendrites.	Mostly dendrites.	Plates with attached dendrites.
Dendri	01	8	10	30	'n	10	'n	10	5	15	75	75	8
5 Plates	8	8	8	8	<b>5</b> 2	8	56	8	85	3	2	52	20
ÅT (°C)	25	25	25	35	22	5	25	55	କ	35	35	35	8
Pour Temp.	0601	1025	1035	1040	1025	1035	1030	1020	1035	1025	1025	1030	1025
Cooling Rate °C/hr.	'n	ß	m	'n	٢	6	'n	7	n	'n	S	n	n
Soak Time (hrs.)	34	•	•	-	4	100	•	•	4	•	•	•	4
Soak Tenp.	1170	1175	1170	1160	1185	1160	1175	1180	1160	1160	0611	1180	0511
Crucible Position	t/1 1+	+1 1/3	+1 1/3	+1 1/3	+1 1/3	11 1/3	+1 1/2	+1 1/3	+1 1/3	+1 1/3	<b>6</b> +	<b>E+</b>	*
Run	3-24	3-25	3-26	3-27	3-28	3-29	3-30	3-31	8 - 3 S	3-33	<b>3</b> -3 <b>4</b>	3-35	3-36

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Good but thin.	Un	<b>9</b> 5	25	1030	u	•	1150	+1 1/2	3-46
Thin plates.	10	90,	25	1025	u	•	1160	+1 1/3	3-45
Thin plates.	15		25	1035	ia.	•	1150	+1 V2	3-44
Thin plates, 1-2 cm <sup>2</sup> good area.	10	50	25	1020	La .	•	1175	+1 1/2	
Thin plates, some dendrites.	25	73	25	1035	i un	•	1170	+1 1/2	3-42
Plates with attached dendrites.	ŝ	8	8	1025	La	•	1150	+1	3-41
Plates with attached dendrites.	ŝ	8	20	1040	UR	•	1160	+1	3-40
Dendritic.	75	8	15	1035	U.	•	1165	o	3-39
Almost all dendrites.	85	15	15	1035	ų	•	1170	0	3-38
Plates with attached dendrites.	ð	£	30	1040	u	►	1180	+2	3-37
Commenta	<b>S</b> Dendrites	S Platio	AT (°C)	Pour Temp. (°C)	Cooling Rate °C/hr.	Soak Time (hrs.)	Soak Temp.	Crucible Position	Run

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<sup>#</sup>Crucible Position column numbers indicate position of the center of the can relative to the center of the furnace in inches.

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TABLE IV

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### Molten Salt Crystal Growth Nuns

Comments	Considerable den- dritic growth.	Plates well formed but thin (bottom cool).	No real plate for- mation.	Wall and bottom nucleation.	Wall and bottom nucleation.	Thin plates but cool walls and bottom.	Tbin plates - acme usable.	No good plates.	Cool walls and bottom.	Considerable den- dritic growth.
5 Dendrites	Ç	8	:	73	8	10	8	2	2	<b>Q</b>
5 Platuo	ç	10	;	33	õ	8	8	8	8	8
	70-75	23	1	i	ł	i	ŗ	:	:	R
Pour Temp.	1035	1025	086	1000	1050	1025	0101	1030	1035	1025
Cooling Rate (°C/hr)	n	a	n	4	m	m L		n	~	en.
Soak Time (hre)	eñ.	ŝ	4 stir	4 8 t i r	4 stir	5 no etá	5 no att	5 no sti	5 no eti	en
Soak Teap.	1190	1185	1180	1160	1150	1160	1160	1160	1160	1165
Crucible Position	1 1/2" above center	2" above bottom	4" above bottom	2" above bottom	3" above bottoe	3" above bottom	4" above bottom	4" above bottom	4" above bottom	1 1/2 above center
<b>Nrnace</b>	10"	10"	ų	19	۲. ۲.	r Ø	1 0	с Ф	r 9	<b>6</b> 1
Run	10-18	10-19	6-10	6-11	6-12	6-13	<b>6-14</b>	6-15	6-16	3-47

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	3-57	3-50	در) : ال	\$. 5 - 5	3-53	ندن + الان	۲.»- ۶	3-30	3-~,	3-4 1	Run	
	1-6	دن ۱ وج	ور ا د ورق	یں ا لا	ور) ۲ مر	ن ا ا	در ۲	3-1	<b>3</b>	3- <b>1</b>	Furnace	
	l" above bottom	2" above bottom	2" above bottom	1" above bottom	1 1/2" above center	1" above center	1 1/3" above center	1" above	l" above center	Center	<b>Crucible</b> Position	
	1200	1200	1200	1200	1200	1200	1200	1180	1170	1190	Soak Temp. (°C)	1. 4
	*	۵	*	•	•	*	•	•	*	•	Soak Time (hre)	fable I
	 U.	•	(m	N	Un	u	UN	u	u	(a	Cooling Rate (°C/hr)	V (Cont'n
	 1000	1020	0101	1035	1010	1040	1025	1020	1035	1020	Pour (°C)	ued)
	-25	-15	1 7-4 10	-20	,	õ	u	10	¢,	15	AT	
	\$	65	70	65	20	35	15	20	0	10	g Plates	
	8	(3) (8)	8	35	80	65	85	80	60	06	S Dendrites	
	Very little plate formation.	Some plates - con- siderable dendri- tic growth.	Bottom cool - wall nucleation but some thin plates.	Very thin - bot- tom cool.	Almost all den- dritic growth.	Considerable den- dritic growth, some plates.	No real plate formation	Almost no plates	Very thin and fragile - ruch den- dritic growth.	Dendritic growth.	Coursents	

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Comenta	Multiple nucleation.	Much dendritic growth.	Some good plates Paper thin.	Dendrites attached to plates (used high ZnO concentration).	Considerable den- dritic growth (high ZnO concentration).	Considerable den- dritic growth (high ZnO concentration).	Very thin polycrys- talline wall nuclea- tion (high ZhO).	Plate formation im- proved - high 2n0 concentration.	Plate looks good - considerable den- drite formation - high ZnO.
A Dendriter	S.	Ş	SE	35	35	Ş	Ş	£	Ş
Plates	8	8	65	Ş	65	8	8	5 0	<b>8</b>
AT (°C)	<b>8</b> -	-25	8	-15	-10	۰ ۱	-13	-10	<b>9</b>
2 4 4 4 2 4 4 4 2 4 4 4 2 4 4 2 4 4 4 4	1(:50	1025	0+11	1(-23	1015	10%0	1040	1050	<b>105</b> 1
Ccoling Rate (°C/hr)	n	n	•	•	n	•	5	¢	đ
Soak Time (Pre)	4	•	•	•	•	•	•	•	•
Soak Temp. (°C)		1200	1200	1200	1200	1200	1160	1200	1170
Crucible Position	bottom	1" above bottom	2" above bottom	2" above bottom	3" above bottom	3" above botton	1" above bottom	2" above bottom	2" above bottom
Purnace 1-1	•	9 <b>- 9</b>		3-3	<b>8 - 6</b>	6 <b>1</b> 1	<b>3 - 1</b>	8-6	3-1
Run	) )	9- <b>50</b>	3-60	3-61	9-03 -		<b>Y</b> O - 6	3-93	99 - E

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		3-75	3-74	3-73	3-7	3-71	3-70	3 - <b>6</b> 9	- <del>6</del>	3-67	
		دیا ء سر	۲ - ۲	3-1	دن ۱ ۵	دی ۱ ده	دی + بر	3-1	دی ۲ ۲	در ۱	Furnace
		4" above bottom	4" above bottom	4" above bottom	3" above bottom	3" above bottce	4" above bottom	4" above bottom	3" above bottom	3" above bottom	Crucible Position
		1200	11 00	1200	1200	1200	1200	1200	1200	1200	Soak
		•	•	•	•	•	•	•	*	•	Soak Time (hre)
		فن	+	IJ	Rj.	×	•	69	2.5	N '7	Cooling Rate (°C/hr)
		10-0	1050	1040	1010	1090	1050	1050	1025	1025	Lend Lend
		ہ جب	-10	ı Ul	-10	-10	r Un	-10	r La	-15	AT
		50	\$	50	55	8	5	ð	60	50	g Plates
		50	8	50	¢	ð	UR UR	8	ð	50	5 Dendrites
ge speciel and a start of the star		Small plates - medi- Nm ZnO, wall nuclea- tion.	Small plates - poly- crystalline, medium ZnO.	Small plates, some dendrites, low ZnO.	Thin plates, some dendrites - low Zn().	Some plate forma- tion - high ZnO.	Some plate forma- tion - high ZnO - wall nucleation.	Wall nucleation - high ZnO.	Thin plate, consider- able wall nucleation - high ZnO.	Multiple nucleation high ZnO concentration	Commente

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Commente	Almost no crystale, rediu: Zno.	Small crystals around edge, medium ZnO.	l" diumeter plate and dendritts, medium 2n0.	Small plates, medium ZnO.	Too much evaporation.	loo much evaporation	Too much evaporation.	Interrupter failed.	Interrupter failed.
A Dendritee	ć	30	Ş	8	8	0	8	* *	4 8
R Plates	# {	8	8	30	10	8	10	: ;	t t
น เวา	-10	۲ ۱	n I	en 1	# # 2	0 9 1	8 4 1	e 6 1	8 4 1
	1050	1050	0601	1050	1020	1020	1020	850	650
Cooling Rate [°C/hr]	a	e	~	1.4	ŝ	sn	•	13	15
Soak Time (hre)	•	•	•	ø	34	24	4	¢	•
Soak Tenp.	1200	1200	1200	1200	1200	1200	1200	1200	1200
Crucible Position	3 1/2" above bottom	4" above bottom	4" above bottom	4" above bottom	Horisontal furnace - front	Horisontal furnace - middle	Hor <b>isontal</b> furnace - back	Horisontal furnace - front	Horisontal furnace - back
Furnace	3=1	3-1	3+1	<b>3-1</b>	Lindberg	Lindberg	Lindberg	Låndberg	Landberg
Run	3-76	3-77	3-78	<b>3-79</b>	3	3	- -	2	3

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ш	L	E	5	2	17	۶	Rea
2 Lindberg	l Lindberg	) lindberg	Lindberg	Lindberg	l.indberg	Lindberg	Turnace
Horisontal furnace - back	Horisontal furnace - middle	Horisontal furnace - front	Norisontal furnace - middle	Horisontal furnace - front	Horisontal furnace - back	Horisontal furnace - middle	Crucible Poertion
1190	1190	1190	1300	1300	1200	1200	Soak (°C)
œ	٥	ø	•	•	•	o	Soak Timu (hre)
1.5	1.5	6.5	•	•	•	15	Cooling Rate (°C/\r)
1000	1000	1000	1025	1025	1025	850	our (°C)
;	8 6 8	8 8 1	8 9 8	8	8 9 8	9 8 5	AT (°C)
8	8	8	50	8	8	8 8	S Plates
8	8	8	50	8	\$	;	X Dendrítes
Too much asporat	Too much export	Too much evporat	26. 🛥 percent Zn	25.5∎ percent Zn	24.7m percent Zn	lnterrupter fail	Competate
8	193	8	Q	<u>.</u>	0.	3	

High concentration 27% percent Medium concentration 26% percent Low concentration 25% percent

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Figure 31 - Cross Section of Molten Salt Crucible Showing Growth Directions of Zinc Oxide Platelets

### Crystal Growth (Continued)

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The center of the furnace is the hottest point, and temperature decreases with distance away from the center. A crucible placed above the center would have the bottom higher in temperature than the top, while below the center the opposite conditions would prevail.

Routine batch weight for a  $ZnO + PbP_3$  run is obtained by filling the crucible with the maximum amount of powdered chemicals which, after melting is only about one-third of the diameter in depth, or quite shallow. Since the temperature gradient is vertical, the temperature difference tends to be established from top to bottom of the melt; however, since the melt is so shallow this difference is small. Therefore, increasing the depth of the melt would increase the temperature difference between top and bottom of the melt.

Also, evaporation of  $PbF_2$  from the welt raises the ZnO content of the welt which can cause nucleation when it is unwanted, i.e., during the soak period. The rate of  $PbF_2$  evaporation should be dependent on surface area of the welt and surface temperature only. For the same surface and surface temperature the rate of evaporation is independent of welt depth.

Therefore, the increase in ZnO concentration for a given amount of  $PbF_2$  evaporation can be greatly reduced simply by increasing the depth of the melt in the crucible.

Generally "double batch" runs were made with only 1. ited success (Table V). It was considered more profitable to pursue the use of lateral gradient in order to grow plates on the surface of the melt in the crucible.

### 3.1.3.2 Lateral Gradient Method

Evaporation of PbF<sub>2</sub> from the surface of the melt causes a thin skin of melt to be enriched in ZnO. With the appropriate vertical gradient, at some temperature during the growth cycle, crystallization should occur at the coolest point in the ZnO enriched surface layer. Though it is conceivable that some other region of the melt could nucleate before the surface skin, in practice, the melts are quite shallow, i.e., depth approximately one-third the diameter, and a significant temperature difference between the top and bottom of the melt seems unlikely.

If the rate of growth across the surface of the melt was to be controlled, it was only reasonable that a lateral gradient be employed to produce the nucleation site near the edge of the crucible.

Modification of the Lindberg furnace (a furnace with a horizontal muffle) to provide a variable lateral gradient was accomplished. Additional thermocouples were installed on

### TABLE V

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## Molten Salt Crystal Growth Runs

Commente	No growth.	No growth.	Tiny crystal plates.	Tiny crystal plates.	Tiny crystal plates.	No plate growth.	Swall plates.	Small plates.	Large plates.	No plate growth.	large plate.	No growth.	No growth.	Large this plate.	Medius plate.
Withdramal Temp (°C)	1050	1210	1060	1055	1050	1000	1095	1070	1040	1000	1040	1020	10 <b>0</b> 0 1	1000	2
Soak Time (hours)	s	34	•	ŝ	4	n	~	•	•	•	13	•	•	<b>16</b> -	•
Soak Temp.	1200	1210	1150	1210	1150	1200	1150	1150	1200	1100	1200	1150	1150	1300	1300
Cool Rate °C/hr.	6 E 3	¥	n	0 N	2.5	2.1	2.2	a.s	'n	2.5	n	2.5	11 11 11	-	n
<b>%</b> Loss	ž	10.8	9.5	15	10	~	3	n	1	10	15	8 8	1	4 T	;
Charge	a	S	• <b>°</b>	°,	S	Q	۵	IJ	۵	<b>*</b> 0	٩	٩	٩	٩	a
Purnace No.	н-з	H-3	L	H-3	د	H-3	H-3	LI LI	H-3	-1	H-3	-1	-	K-3	K-3
Run	189	190	161	192	193	1944	1948	195	196	197	196	199	30	105	89

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2	No.	Charge	% Loss	Cool Rate °C/hr.	Soak Temp.	Soek Time (hours)	Vithdrawal Temp. (°C)	Commen te	
03	H- 3	Ð	;	La	1200	u	10-00	Large plate.	
<b>D</b>	H- 3	٥	;	u	1200	U.	1030	Large plate.	
<b>B</b>	0"	S	8	ų	1200	i,	1025	Medium plate.	
<u>Š</u>	H-3	S	8 3	•	1300	u	1050	No growth.	
9	0.1	S	8	•	1200	(a	1050	Medium plate.	
ŏ	H-2	۵	1		1200	U.	10 <b>50</b>	Small plate.	
Ş	H-3	S	•	•	1200	ų	1040	No growth.	
011	H-2	۵	2	œ	1200	u	10 <b>00</b>	No growth.	- 74
11	0 1	S	:	3. <b>5</b>	1200	u	1050	No growth.	
112	H-3	۵	8	•	1200	ia	1050	No growth.	
113	H-2	ú	•	•	12	La	10 <b>50</b>	Small thin plate.	
214	H-2	۵	:	3.1	1200	u	1050	No growth.	
1154	۲	ß	25	3.1	1200	ሁ	1050	B <sub>2</sub> O <sub>3</sub> - small plate.	
158	۲	ŝ	12	3.1	1900	u	10 <b>50</b>	Small plate.	
116	H- 2	S	40	<del>ن</del> ا	1300	u,	1050	Medium plate.	
1177	۲	S	22	<del>د</del> ا	1300	ų	1050	Medium plate-BgOy added.	
1174	٦	s	16	Û	1200 💡	u,	1050	Medium plate.	

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Soak Soak Withdramal Temp. Time Temp. (°C) (hours) (°C) Commente	1200 5 1050 Medium plate.	1200 5 850 Nc growth.	1200 5 1055 No growth.	1200 5 1050 No growth.	1200 5 1050 No growth-B <sub>2</sub> O <sub>3</sub> added.	1200 5 1050 No growth.	1200 5 1050 No growth.	llso 8 loso No growth.	1150 5 1050 No growth.
Cool Rate C/hr	25	9 2.5		•	•	2.5	2.4	13 3	<b>5</b> 1
Charge	S	S	S	S	S	S	S	۵	<b>*</b> D
Furnace No.	H-2	H-5	H-2	H-5	L	H-3	H-3	<b>5</b>	41
Run	218	219	320	221	122	223	324	226	227

+ and - refer to alightly greater or lesser amounts of ZrO.

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D - Double charge - 99.0 gms. ZnO, 801.0 gms. PbFg, 900.0 gms. fotal.

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### Crystal Growth (Continued)

either side of the position where the crucible is placed, Figure 32. By means of these thermocouples, the actual gradient across the diameter of the crucible could be measured at any time during a run.

Tests showed a gradient of  $35^{\circ}$ C across the crucible; therefore at a cooling rate of  $5^{\circ}$ C per hour solidification should advance from the nucleation site on one side of the crucible to the opposite side of the crucible in seven hours.

Another attempt was made to achieve lateral gradients in a vertical furnace by removing two of the heating elements from the circuit. In essence this created a cool side on the muffle. A temperature gradient of  $7^{\circ}$ C across the melt was achieved, in Furnace H-3. This gradient was measured by means of two thermocouples which were strapped to the pedestal, Figure 33. In cooling the furnace, therefore, nucleation should occur only on one edge and continue across the top of the melt.

Some success was achieved using this furnace and technique. The plates though somewhat larger were still thin. While the importance of thermal gradient effects proved to be significant it became clear that such gradients were not the only factor in determining the size, thickness and quality of ZnO plates grown by this technique.

As the hydrothermal crystal growth improved it appeared that, although the gradient control could be developed to produce larger crystals, the hydrothermal seed problem would most readily be resolved by utilizing the hydrothermal system to generate its own seeds.

### 3.2 Hydrothermal

### 3.2.1 Low Pressure Crystal Growth

Shortly after the program was begun Laudise, Kolb and Caparaso<sup>8</sup> published a paper in which they described a set of conditions at which ZnO crystals could be grown using the hydrothermal technique. As such the conditions provided an excellent "jumping-off point" for the contract. After several preliminary experiments with the autoclave pressure testing, furnace calibration and pressure balance, the first attempts were made to grow crystals. The major differences between the two laboratories were in the sizes and types of autoclaves. The ZnO crystal growth was developed at Fell Telephone Laboratories using rather small chambered silver-lined Morey type vessels (maximum internal cavity size  $1-3/16^{\circ}$  diameter x  $6-7/8^{\circ}$  long). The Airtron vessels have been previously described in this report.

The first attempts at crystal growth failed using the Bell Telephone Laboratories' parameters. The most apparent reason for failure was in the warm-up procedure. The warm-up procedure employed by Bell Telephone Laboratories was what would be considered slow,





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### Cryvtal Growth (Continued)

i.e. over a twenty-four hour period. Because of the difference in autoclave geometry, silver liners, etc. this approach did not work at Airtron. Instead it was found that with this procedure in many cases the seeds would be completely dissolved. This was not unreasonable since the seeds wore only 10-15 uils thick and the volume of solution was approximately 1.3 liters.

After some experimentation with warm-up procedure it was found that the best technique at Airtron was to warm up the vessel to operating conditions as quickly as possible. In this way the seeds were ratained and the growth of crystals begun. The data for the initial growth runs with the warm-up procedure experiments is presented in Table VI, and a photograph of some typical crystals are shown in Figure 34.

Once having obtained a suitable warm-up procedure the following task remained:

- 1) To improve the quality of the crystals.
- To eliminate the corrosive attack of the silver container (see section 3.2.4).
- 3) To attempt to obtain uniform growth rates at all seed positions by baffle area changes, and changes in the amounts and position of insulation.
- 4) To maximize the growth rate yet maintain or improve the crystal quality.
- 5) To develop high quality seed crystals of large basal area by successive hydrothermal growth rune. (see section 3.2.2)

Work on the above objectives was performed during runs No. 44 through No. 63. The operational crystal data for these runs is presented in Tables VI and VII. With regard to objectives 2 and 5 the results and discussions of these are presented in separate sections of this report. An idea of the improvement in quality during this period can be obtained by comparison of the crystals shown in Figure 34 (Run No. 39) and Figure 35 and Figure 36 . Figure 36 is the top section of a crystal from Run No. 51 in which the seed was removed.

The improvement in growth rate uniformity can be seen from the data presented in Tables VIII and IX which summarizes the growth rate for each crystal for Runs No. 46 through No. 54. In general it was found that the seed(s) in the uppermost position were the fastest growing. This is to be expected since it is the one which sees the greatest  $\Delta T$ . The seed(s) nearest the baffle exhibit the lowest growth rate because it is the one with the lowest  $\Delta T$ . In order to obtain a

### TABLE VI

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# Crystal Growth Operational Data

33	3	31	30	29	<b>3</b> 0	27	Run
2	Ξ	:	3	1	-	6 molal KCH pressturated with ZnO 0.2 molal LiCh added	Solvent
	:	=	=	:	Ŧ	ZnO eintered at 1150°C for 2 hrs., broken into 1/4" to 3/8" chunks	Nutrient
	83	83	3	83	<b>8</b> 2	<b>G</b> W	Internal fill (ailver can) %
70.6	70.5	70.6	70.6	70,6	70.6	70.6	External fill %
10	12	12	10	10	Э	۵	Baffle Area M
ມ <b>ນ</b>	24	24	2	24	2,	24	Warm-up Time (hre)
36	ğ		20	24	17	18	AT (°C)
Seeda thick- ened	Almost no growth	No growth seeds dis solved	Growth on seeds	Some growth	Snee growth	Some growth	Regulto
1 day at opera- ting conditions.	Took insulation bout of center section of fur- nace.	t Used aide hest- - ers in addition to hot plate.	Hot plate and aide unitu, fill error, can ciushed.	Weld leaked.	Weld leaked, thin seeds dissolved.	Weld leaked seeds thickened.	Consente

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Consert	Operated 1 day to check pres- sure balance.	Hot piate only - check warm-up procedure.	Can puffed - fill balance off - erterior low.	Can puffed.	Autoclave seal leaked, can burat - anto- clave evertmated.	Brat.	Autoclave seal leaked, grind- ing incorrect.	Balance looke good.	
Results	Seeda thickened	Seeds thickened	Spontan- eous nuc- leation	Some Growth	Spontan- eous nuc- leation	Some growth on 13 areds	Some growth	Some Browth	
	4	9	<b>6</b> 0 40	9	75	Ş	20	\$	
Marm-ur rige (hrg.	6	<b>\$</b>	45	33	8		с 36 обдар уни. Ф Ф	**************************************	
Baffle aifa %	10	10	10	12	10	10	10	10	
External f(11 5	70.6	70.5	70.6	71.5	7.5	76	77.0	77.0	
Internal fill (silver can) %	6	<b>6</b> 61	8	۲. ع)	e B	6 0	6 8	e 9	
Mutrient	ZnO sintered at 1150°C for 2 hrs., broken into 1/4" to 3/8" chunks	z	z	Ξ	£	2	-	:	
Solvent	6 molal KOH presaturated with ZnO 0.2 molal LiOH added	Ξ	÷	=	Ξ	Ξ	=	ىر =	
	4	<b>9</b>	<b>90</b>	37	<b>6</b>	6	9	Ŧ	
			-8	81-				:	ж. •

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Figure 34 - Hydrothermally Gr-\_n Zinc Oxide Crystals

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TABLE VII

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## Crystal Growth Operational Data

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	Leaked	l waked.				First hydrothermai seeds.	Sweda Arom No. 46.			Seeds from No. 49.	First bigh pressure run.			
<pre>&lt;0001&gt; Average Growth Rate (mils/day)</pre>	1 \$		10.6	5.9	7.●	14.4	9.0	11.7		7.9	20.0	9.1	10.7	19.7
Operating Time (days)	:	:	28	29	7	11	23	38	43	34	v	16	33	14
LLOH Conc.	1 1 1	1 5 8	0.3	0.2	0.2	0.3	0.2	0.3	0.3	1.0	0.3	0.2	0.2	0.3
P (psi)	3 8 8 8	1	7500	7500	6400	8300	0069	7500	6500	1700	17000	7700	10500	7500
	;	t T	S	37	õ	\$	35	52	8	16	16	36	30	31
T, C,	    	8 1 6	288	293	395	295	305	295	310	396	390	295	297	362
TH (°C)	1 1 8	ŧ 2 1	304	394	295	285	8	390	30	294	295	299	399	562
TB.		1 6 1	338	330	325	325	335	315	330	375	326	325	328	330
Run No.	42	43	\$	\$	4	47	48	40	8	51	52	53	54	33

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baffle.									
l inch vessel, 15%	31	11	0.2	23000	25	390	393	415	62
Failed during ware-up.	;		0.2	8 8 8 9	† 1	3 8 8	8 8 8	1 1 1	61
l inch vessel, 7.5% baffle.	1	u	1.0	19700	15	327	328	341	8
 Silves attack. Flawed growth - VMOF.	18-23	15	0.2	19400	12	388	38 <b>8</b>	8	2
No ellver attack. VMOF - seed develop- ment.	1-3	<u>د</u> و	1.0	8000	15	317	317	332	<b>6</b> 3
Au plated can.	7	42	1.0	9000	15	313	313	328	59
	3. <b>5</b>	13	0.2	8500	15	317	317	33 <b>2</b>	58
Leaked.	8	<b>;</b>	8 2 6	8 9 8 8	ł	t 8 1	1 3 4	1 9 9	57
Leaked.	•	8 7	: 4 9	8 8 8	1 8	8 8 1	1 1 1	7 7 1	56
Nedarks	<0001> Average Growth Rate (mile/day)	Operating Time (days)	LiOH Conc. (m)	P (p=1)	AT (°C)	IT (°C)	TH (°C)	IB (°C)	Run No.

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Figure 35 - Hydrothermally Grown Zinc Oxide Crystals

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Figure 36 - High Quality Crystal from Run No. 51 with Seed and c Side Removed TABLE VIII

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# Seed and Crystal Data for Run No. 44

<pre>&lt;000[&gt; Growth Rate* [mile/day]</pre>	5.5	0			. 4						0		
<0001> Growth Rate [mile/day]	8.6	<b>6</b> .9	<b>*</b> •	× 9.1	×.0	<b>N</b> • •	<b>9</b> <b>1</b> 2 - 10 - 10 - 10	₹<10 <b>3</b> *Q	n i ta koju	1923 - MARINA	<b>R</b> <b>J</b>	S 1985 Ber oa	۹ ۱۹ وژند ۱
Total Growth Rate (mile/day)	14.1	10.8	11.6	14.3	14.4	10.9	10.3		10.0	<b>5.</b> 0	<b>6.9</b>		
(ocof) Thickness (sile)	154	137	145	145	136	126	122	109	59	2	56		
(0001) Thickness (mile)	341	166	179	255	267	178	145	961	187	125	117		
lotal Thickness (mile)	395	303	324	<b>007</b>	<b>4</b> 03	306	287	245	379	149	173		
Weight (grame)	12.9	9. 9	4.4	8.1	7.1	4.4	4.0	1.8	<b>9</b> . <b>4</b>	1.3	2.8		
Rack Position	<b>~</b>	1	n	M	(1	en.	ę	•	•	÷	n		

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•Neglecting Thickness of Seed.

Rack Pogition	Weight (grame)	Total Thickness (milm)	(0001) Thickness (mils)	(000I) Thickness (mile)	Total Growth Rate (mils/day)	<0001> Growth Rate [m11e/day]	<000[> Growth Rate (mile/day)
м	33.6	233	176	57	8.0	6.1	2.0
•	20.1	206	153	53	7.1	<b>5.</b> 3	1.8
ω	5.7	191	116	75	6.6	4.0	2.6
•	17.5	190	151	96	6. <b>6</b>	5.2	1.3
Un .	9.5	153	113	\$	5.3	3.9	1.4
٥	<b>9</b> , 3	109	109	o	3,8	3.8	0
o	2.2	118	118	0	4.1	4.1	o

### Table VIII (Continued)

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Seed and Crystal Data for Run No. 45

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TABLE	IX.
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### Seed and Crystal Data for Rans No. 46 Through 54

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Run No.	Rack Position	Seed Weight (gms)	Seed Thickness (mils)	Crystal Thickness (sile)	Growth Rate (mils/day)
46	1	3.1		53	
	2	5.6		62	ě
	3a	3.0		47	7
	36	1.6		50	7
	44.	4.3		71	10
	<b>4b</b>	24		84	12
	5			n - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 19	
	64	1.6		44	● · · · · · · · · · · · · · · · · · · ·
	65	1.7		54	8
	72	1.8		48	7
	75	1.7		49	7
47	1	21.1	64	273	10
	2	24.7	57	244	17
	3 <b>a</b>	12.5	59	235	16
	3b	14.4	49	236	17
	<b>4a</b>	11.5		180	16
	<b>4</b> b	5.3		163	14
	5a.	6.2		150	13
	5b	8.0		154	11
	08	5.0		169	15
	<b>0</b> 0 7.	5.1		125	11
	78	4.2		147	11
	78	4.4		138	13
48	1	18.5	53	259	9
	2	34.1	62	322	12
	34	16.3	47	233	٤
	3b	10.0	50	243	9
	<b>4a</b>	21.4	71	295	10
	<b>4</b> b	5.5	84	200	5
	5	10.4	36	289	11
	64	9.8	44	238	9
	6b	9.8	54	254	9
	78	9.1	48	225	8
	76	10.0	49	244	9
49	1	55.1	55	400	12
•	2	20.8	44	365	11
	3	56.8	42	450	15
	4	10.5	43	343	11
	5	18.3	48	. 382	12
	0	50.0	40	371	12
	7	12.2	49.	<b>29</b> 3	9

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### Table IX (Continued)

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		Seed	Seed	Crystal	_
	itack	Weight	Thickness	Thickness	Growth Rate
Run No.	Position		<u>(uils)</u>	(mile)	(mile/day)
50	1	96.7	322	655	8
	2	59.5	230	588	5 A
	3	41.5	295	507	
	4	27.8	109	418	<b>'</b>
	5	32.1	153	409	
	6 <b>a</b>	27.0	238	442	2
	6L	16.4	200	391	2
	7 <b>a</b> .	28.8	243	477	2
	76	25.7	254	461	•
	8	26.3	289	521	0
51	1	4.9	39	372	10
	2	7.6	65	381	9
	3	6.6	54	404	10
	4	5.1	43	315	8
	5	5.9	60	261	0
	6	5.1	39	277	7
	7	5.7	55	223	5
	8	1.6	21	98	2
52	1	0.7	10	197	31
	2	5.0	63	217	20
	3	1.3	30	216	31
	4	3.7	135	418	47
	5	2.2	32	182	25
	6	2.8	34	193	27
	7	2.9	36	190	26
	8	1.5	30	155	21
	9	. 8	64	145	14
	10	1.8	35	153	20
53	1	11.7	80	426	11
	2	8.4	57	425	12
	3	7.4	54	338	9
	4	8.9	61	392	10
	5	8.2	63	325	8
	6	11.0	88	353	8
	7	7.5	53	309	8
	8	5.2	47	280	7
* 54	1	8.4	44	348	14
	2	9.4	53	307	13
	3	9.1	43	325	13
	4	7.9	47	273	10
	5	9.3	50	278	10
	6	5.5	37	227	9
	7	8.4	49	127	8

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### Crystal Growth (Continued)

uniform growth rate it is necessary to make the growth chamber as nearly isothermal as possible. This could only be accomplished by adjusting the baffle area (5 - 10%) and experimenting with the quantity and position of ineulating material on the top of the intoclave.

Furing this period it was found that at rates in excess of 15 mils/day the crystal quality was generally poor and that the slower the rate the higher the quality. The lower quality was manifested by crevice flawing resulting from differences in growth of the < 10I1> and <0001> directions.<sup>8</sup> While the presence of Li<sup>+</sup> aided in reducing this crevice flawing, growth rates of 15 mils/day were still too great to result in high quality.

The crystal structure of ZnO is such that the <0001>and <0001> are not equivalent and therefore the growth rates in the two directions are not equivalent. It was found that the rates is the <0001>or c<sup>+</sup> ware 2-3 times faster than the <0001> or c<sup>-</sup>. In addition to the anisotropy of growth rate the quality defects were of a different nature. The crevice flawing previously described occurs in the c<sup>+</sup> direction. The defects on the c<sup>-</sup> faces were in the forms of dendritic growth along the <1011> direction.

The anisotropy of the electrical resistivity of material in the  $c^+$  and  $c^-$  sides of the seed will be discussed in a later section of this report (4.2.1).

The following summary gives the conditions which were found suitable for the growth of high quality crystals at low pressure conditions at that time:

Crystallization Temperature	~900°C
Nutrient Temperature	~930 °C
AT	~30°C
Pressure	8000 psi
Solvent	6aKOH
Lithium Concentration	1.2-2.0 =
Seeds	High quality
Warm-up	As fast as possible
Natrient	Sintered ZnO powder
Baffle Area	7.5-10%
Autoclave	3 in. i.d.
Silver cap	2.0 in o.d.
Internal fill	8 35
External fill-	785

### 3.2.2 Hydrothernal Seed Development

During the course of the contract a program was begun to use the hydrothermal system to produce large area seed crystals. This program had not been anticipated at the beginning of the contract since in its original concept the large seeds were to be obtained by

### Crystal Growth (Continued)

the molten salt technique. As the contract progressed, however,

- 1) the molten salt technique failed to yield reproducibly large high quality crystals.
- it was found that hydrothermal crystals could be sliced and used as seeds for subsequent runs.
- at conditions where high quality growth was produced a "healing effect" of cracks and other defects took place during the crystal growth and,
- 4) in addition to obtaining gr with in the (c<sup>\*</sup>) and (c<sup>\*</sup>) directions, significant lateral growth i.e. in the (a) and (m) directions, also took place thus enlarging the basal area of the crystals.

It therefore seemed appropriate to begin a program wherein the largest hydrothermal crystals of reasonably good quality would be sliced into a seed crystal and used in the subsequent run.

This program was begun using a high quality seed whose area was 9.2 cm<sup>2</sup>. Table  $\chi$  summarizes the data for the development of the seeds giving an indication of the increase per run over a four run period. Figure 37 also shows several crystals from subsequent runs to indicate the increase in crystal size from run to run. The increase in size as shown in the figure and table is indicative of the way-increwhich the program progressed. Finally in the growth of large 150 gram crystals the basal area of the crystals was greater than  $28 \text{ cm}^2$ . The average growth rate in the (a) and (m) directions during this period was found to be 4-5 mils per day.

One problem which was discovered in the lateral growth during this period was concerned with the observations of a phenomenon known as "electrical twinning." This growth defect was first noted in the crystals grown in run No. 59 which utilized a gold plated can.

The crystals were examined with a U-V mineral-light  $(3660A^{\circ})$  which caused almost the entire (0001) surface of the crystal to have a yellow fluorescence. The (0001) surface only fluoresced below that area where the (0001) surface did not fluoresce. Further examination of the crystal surfaces showed that on both sides of the crystal the areas which fluoresced were smooth, and not flawed. It appeared that these smooth areas which fluoresced might be (0001) faces and that a reversal of crystallographic orientation had occurred. Such a reversal would account for these observations such as shown in Figure 38. Btching the crystals in sodium hydroxide solutions was found to reveal the differences in orientation quite nicely. On the (0001) surface the etch produces a matte appearance while the (0001> than the <0001> and as a result an etched (0001) surface, the material just described, will have islands of (0001) surface where this orientation

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Ran_No.	Basal Area (cm2)	<u>A</u> c=2	Rate (cm²/day)
51	9.2		****
53	12.4	3.2	P. 103
. 54	15.4		· · <b>0</b>
55	19.4	3.9	<b>G. 278</b>

SUMMARY OF DATA FOR BASAL AREA INCREASE



Figure 37 - Crystals from the Seed Development Runs Showing Basal Area Increase

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### Crystal Growth (Continued)

reversal occurs. This type of orientation reversal has been found to occur in quartz and is called "electrical twinning."

Etching of ZnO crystals in 10 m NaCH at 90°C for 15-30 minutes was found to develop different etch figures or patterns of the opposing pole faces. The figures are somewhat different than those reported by Mariano and Hanneman<sup>2</sup> who used a HNO<sub>3</sub> etch. In this case the (9001) faces etch very quickly leaving the surface with a somewhat dull finish. The (9001) faces etch more slowly and are shiny except for the pit produced by the etch. Typical etch gtructures are shown in Figures 39 and 40 for the (9001) and (9001) faces, respectively. The patterns on the (9001) surface is formed by the production of hillocks on the surface having the appearance of small hemimorphs in agreement with the natural crystal morphology. Two patterns are present on the (9001) surfaces. One is the pits which appear as hexagonal or parallelogram-shaped pits with flat bottoms. The other is a pattern or network of lines which may be slip lines and due to the microscopic.imperfection of the crystals.

These etch patterns clearly reveal the existence of pole reversal in the crystals when the various sections are examined microscopically. The areas of such electrical twins on a grown crystal are shown in Figure 41.

Unfortunately the seed development program was slowed down by the discovery of such twins. The edge of the seed plate thereafter was trimmed of any of the "electrically twinned" material thus reducing the basal area. Nonetheless the programs success is notable when the final seed plate area and large crystal growth are considered.

### 3.2.3 High Pressure Crystal Growth

The dramatic increase in growth rate with increased pressure in the hydrothermal growth of  $ruby^{13}$  led to speculation of what might happen in the case of ZnO. The only reason at that time for operating below 10,000 psi was that this was the region used by the Bell Laboratory workers, who were limited by the pressure capability of their vessels.

The first high pressure ZnO run attempted at Airtron produced relatively high quality crystals and at what appeared to be higher growth rates.

Subsequent runs indicated that the rate is undoubtedly more dependent upon crystallization temperature,  $\Delta T$ , impurities than pressure. The growth rate in this first experiment was 26.0 mils/day, Run No. 52. Although no subsequent run was made at exactly the same conditions at even higher pressures much lower growth rates were obtained. Scanning Table XI will reveal that lower rates were observed even when the variables other than pressure might be expected to produce higher rates.


Figure 39 - NaOH Etch Pattern on (0001) Surface



Figure 40 - NaOH Etch Pattern on (0001) Surface



Figure 41 - Phtomicrograph of ZnO Blectrical Twins After Etching

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TABLE XI

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# CRYSTAL GROWTH OPERATIONAL DATA

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R en c i k s		Best Growth to Aste		Crevice flamed or mail	Seed Dovel mane Ban		Metallic Zn addad	Ch Dobrd Pun	30.0 0m Cu0 added	3.1 Ge Zo estal adda	24-1 9 Qu0 + 3 98	the fail ackad		50 gm CuO, 3 gk Cu metal + 0.25 mg Zn added	3.0 gm Zn added- large crystal run	
<pre>&lt;0001&gt; Average Growth Rate (mile/lay)</pre>	L	16	<b>9</b> .0	11	- E) -0	4, 6	a. u	10.0	<b>11</b>	12.0	15.0	•			10.9	- Continued
Operating Time (days)	38	15	18	15	31	10	untanta ( , g , s ₹	, »"" 10	Sec.		<b>.</b>	\$		·· <del>«</del> ∙ <b>}</b>	99 - S	
L1 OH Conc (=)	1.0	1.0	1.0	1.5	1.0	1.0	1.0			a		1.0			1.0	
Pressure (pai)	9,700	19,700	19,200	19,500	9,100	19,800	33,400	23,300	15,700	28,200	16,300	24,500	13,400		26,000	
ΔT (0°)	19	14	7	æ	16	vo	22	24	51	38	18	8	11		36	
T (01)	316	371	376	389	321	389	277	286	333	373	332	274	385		274	
(ko)	316	371	374	389	318	388	274	282	332	266	3 <b>32</b>	270	383		270	
TB [0]	335	383	383	39.7	337	39 <b>5</b>	299	310	352	90E	350	<b>308</b>	395		310	
Run No.	65	99	67	68	69	8	11	2	61	74	75	76	77		78	
								-99	<b>}-</b>							

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				**************************************	ante de an		و بر معدد ماده معدد ماده			•···	· ·		1.4.
			•	85	. 2	83	8	91	e C	79	Run No.		
				312	312	<b>31 3</b>	312	313		310			•
				271	298	296	270	299		270			•
				275	294	290	274	295		274	TT (0°)		
; •				ð	16	20	ŝ	16		38	4T		
!				25,200	22,400	25,000	25,500	22,500		26,000	Pressure (psi)	TABLR XI (	
<b>}</b>				1.0	0.40	0.75	1.0	1.0		1.0	LiOH Conc	(Continue	
! *				56	29	23	56	8		8	Operating Time (daya)	ă)	
1 *	in .	· · · ·		3.7	<b>0</b> . 0	7.4	7.1	10.3		10.9	40001> Average Growth Rate mils/day		
a				3.0 gm Zn added - large crystal run	1.5 inch vessel - doping run	<pre>1.5 inch vessel = doping run</pre>	2.0 gm Zn added - large crystal run	1.5 inch vessel- doping run	Vessel leaked	2.0m Zn added - lârge crystal run	Renarko		•
<b>a</b> •				-	100-								
:	<sup>*</sup>	,											P

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#### Crystal Growth (Continued)

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When the number of possible variables in the system are considered it is obvious that the total number of runs made throughout the course of the contract could not possibly examine each one thoroughly. Furthermore, even reducing the number to what are probably the principal ones i.e. crystallisation tomperature, AT, and Li<sup>\*</sup> concentration, it is obvious that the number of exploritory runs could not possibly be expected to yield exact curves which could be used to interpret the crystal growth results. At best these few runs, summarised in Table XI, can only be interpreted as trends and compared to those of other more documented hydrothermal crystal growth systems. By approximately selecting the runs so that all but one of the other parameters are approximately the same in value, some comparison and conclusions can be extracted.

For instance the growth rates for Runs No. 62 and 71 are 31 mils/day and 5.4 mils/day, respectively. If the difference in Li<sup>+</sup> content is neglected at the other variables except temperatures are nearly the same. As would be expected the rate increases as the temperature increased just as in quarts<sup>9</sup> and ruby <sup>13</sup>.

Similarly comparing the runs made for the growth of 150 gm crystals (the last five in the table) with Run No. 74 some indication of Li<sup>+</sup> effect on growth rate can be seen. The large crystals were grown with 1.0m Li<sup>+</sup> ion present in the growth fluid. In Run No. 74 the Li<sup>+</sup> was inadvertently omitted from the run. The temperature pressure, and  $\Delta T$  conditions were nearly identical for all runs so that the almost double rate in the case of zero lithium must be due to the impurity effect.

If now runs No. 62, 66, 68, and 70 are considered and the difference in Li<sup>+</sup> content is disregarded, one can see the effect of  $\Delta T$  on growth rate as with quarts and ruby. The increase in rate with  $\Delta T$  appears to be linear (Figure 42).

The last five runs listed in Table XII also demonstrate the reproducibility in the process. The difference in rates in these five runs is only 2 mils/day. As can be seen from the data in this table and also Table XIII the crystals were grown under vory similar conditions and the growth rates from top to bottom of the chamber is quite uniform. The data prove that the system can be run in a production manner for the manufacturing of large zinc oxide crystals.

The growth parameters found most suitable for the growth of these large crystals are summarized below.

Nutrient Temperature	312°C
Crystallisation Temperature	274°C
ΔΤ	38°C
Pressure	25,000 psi
Base Concentration	5 m KOH
Lithium Concentration]	L.O m LiOH

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	Summery of	Selected	High Press	ure Crystal G	ourth Date
Run No.	T cryst. (°C)	Δ <b>Τ</b> ( <sup>●</sup> C)	Р ( <u>pei)</u>	Li <sup>+</sup> cenc.	-DODI> Rate (uils/day)
62	390	25	23000	0.2	31
64	388	12	19400	0.2	20
66	371	14	19700	1.0	16
68	389	8	19500	1.5	u
70	309	•	19000	1. <b>9</b> 5545 (100)	and the second
71	277	22	33400	1.0	5.4
74	273	38	28200	0	12.0
81	295	16	22500	1.0	10.3
83	290	20	25000	0.75	7.4
84	294	16	22400	0.40	8.6
76	274	36	24500	1.0	7.8
78	274	30	26000	1.0	7.0
79	274	38	25500	1.0	6.3
82	274	40	25500	1.0	7.1
85	273	40	25 200	1.0	5 7

TABLE XII

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		SEED AND C	RYSTAL DATA	FOR RUN N	io. 58	
Crystal	Weight	(grams)	Thicknes	s (mils)	Growth	Rate
No.	Before	After	Before	After	(grame/day)	(mils/day)
14	13.2	25.1	90	1 37	.9	3
18	2.2	3.0			.06	-
10	<b>25.</b> 7	38.7	148	21 3	.87	5
28	10.1	19.3	76	119	.67	3
28	26.2	37.1	174	226	. 79	4
- <b>3</b> A	5.1	12.3	42	77	.53	3
38	18.6	29.8	107	155	. 81	3
44	10. <b>6</b>	13.3	329	430	. 19	7
48	18.3	28.3	104	148	. 72	3
SA	18.7	31.1	73	123	. 80	4
58	6.2	12.8	49	62	. 47	2
64	<sup>12</sup> <b>20.</b> 0	28. <b>2</b>	1 35	171	. 59	3
68	7.2	14.0	55	80	. 49	2

TABLE XIII

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## TABLE XIII ( Tont' mued)

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#### SERD AND CRYSTAL DATA FOR RUN NO. 59

Crystal	Weight (grams)		Thicknes	s (mile)	Growt	Growth Pate		
40.	Before	After	Before	After	(grams/day)	(ails/day)		
14	25.1	89.7	137	367	1.5	5		
18	3.0	10.7		~ = =				
10	20.1	110.7	80	366	2.2	7		
2A	12.3	61.5	77	3 <b>66</b>	1.2	7		
28	17.1	113.3	68	3 <b>58</b>	2.3	7		
<b>A</b> E	29.8	102.8	155	465	1.7	7		
35	18.6	108.9	84	348	2.2	6		
44	28.3	97.2	148	391	1.6	6		
48	28.2	116.7	115	405	2.1	7.		
5A	13.3	33.0	4 30	7 <b>87</b>	1.0			
58	16.9	98.4	62	3 <b>42</b>	1.9	7		
64	38.7	93.3	<b>∠13</b>	434	1.3	5		
6B	17.4	84-0	82	297	1.6	5		
		SEED AND	CONSTAL DAT		NO 60		,	
		SEED AND	CRISING DAI		10.00			
1	2.8	<b>9</b>	5 <b>6</b>	62	~ * *	-		
2	3.6	3.7	60	65		-		
3	3.0	2.9	46	50		-		
4	2.7	2.3	48	50		-		
		SEED AND	TYSTAL DAT		ND 62		:	
			CRISING DAIL				•	
1	1.6	19.7	40	38 <b>3</b>		31	•	
2	2.8	14.0	88	347		24	•	
3	1.0	5 <b>.5</b>	48	18 <b>2</b>	~~~	12		
4	1.4	2.9	56	140		8	;	

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Crystal	Malcht	(grats)	Thicknes	e (mils)	Growth i	Rate
No.	Before	After	Before	After	(grame/day)	(mile/day)
1A	10.2	15.3	61	148		2.6
18	5.4	27.5	34	110		2.3
2A	9.4	21.6	59	133	<b>**</b> •	2.2
2B	2.9	5.7	62	126		1.9
2C	19.0	41.4	AQ	225		4.5
34	11.5	23.8	75	153		2.3
38	1.3					~ = =
3C	14.6	26.6	94	157		1.9
44	16.0	34.1	79	164		2.7
48	10.5	21.3	72	135	•••	1.9
5 <b>A</b>	11.1	21.4	67	134		2.0
5B	13. <b>5</b>	21.1	94	138	* * *	1.3
<b>6</b> A	12.9	<b>22</b> .8	77	127		1.5
68	10.3	18.9	70	123		1.6

SEED AND CRYSTAL DATA FOR RIN NO. 63

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Crystal No.	Weight Before	(grame) After	Thicknes: Patore	e (mile) After	(grame/day)	th Rate (mils/day)
14	17.7	2.1	65	452		22.8
18	10.6	13.4				
24	13.7	64.3	81	409		18.8
28	8.2	53.3	61	372	- #1	18.3
34	2.8	11.0	63	191		7.5
38	18.3	73.9	71	415		19.7
ۍ:	11.2	56.2	64	301	<b>**</b> *	13.9
48	9.8	50.8	32	316		14.4
SA	7.7	48.9	44	258	***	12.6
58	26.2	78.8	89	3 <b>58</b>		15.8
6 <b>A</b>	12.5	43.7	79	278		11.7
6B	14.7	47.6	62	319		15.1

## SEED AND CRYSTAL DATA FOR RUN NO. 64

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Crystal	Whitcht (grams)		Thicknes	s (mile)	Growth Rate		
<u>No.</u>	Befere	ofter	Before	After	(grams/day)	(alls/day)	
1A	21.4	90.1	131	472	1.81	9.0	
18	з. б		62				
10	15.2	60. <b>1</b>	106	330	1.18	6.1	
2A	21.1	86.5	133	419	1.72	7.5	
28	5.6	24.7	130	360	0.50	6.1	
34	22.7	97.7	125	393	1.97	7.1	
38	21.3	70.3	133	336	1.29	5.3	
4.4	2.4	17.8	55	297	0.40	6.4	
48	18.7	78.5	122	428	1.57	8.1	
4C	3.3	18.8	61	293	0.41	6.1	
5A	11.3	62.7	81	343	1.35	6.9	
5B	9.8	57.6	66	331	1.26	7.0	
64	4.6	30.1	57	275	0.67	5.7	
6B	1.8	13.3	53	291	0.30	6.3	
6C	7.7	46.4	68	332	1.02	7.0	

## CEED AND CRYSTAL DATA POR RIN NO. 65

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Sec.

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# SEED AND CRYSTAL DATA FOR RUN NO. 66

Crystal	Weight	(grame)	Thicknes	e (mile)	Growt	h Rate
NO.	Before	After	Before	After	(grams/day)	(mile/day)
18	16.2	95.1	72	384	5.24	21.0
18	17.7	32.5		• • •	0.99	***
1C	21.1	97.4	70	409	5.08	22.6
28	14.4	74.9	68	326	4.04	17.2
28	9.9	57.9	67	312	3.20	16.3
AE	9.0	61.5	58	296	3,50	15.9
38	13.3	72.5	74	337	3.95	17.5
44	11.0	29.1	191	362	1.21	11.4
48	9.6	59.6	62	31.3	3. 34	16.7
5 <b>A</b>	7.6	48.1	44	236	2.70	12.8
5B	6.7	34.6	85	333	1.80	16.5
64	5.4	27.1	84	284	1.45	13.3
68	15.2	63.7	83	304	3.24	14.7

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Crystal	#eight	(grms)	Thickness	(mils)	Gr ou	th Pate
No.	Before	After	Before	After	(grams/day)	(mils/day)
1A	13.0		76			-
18	2.4		60	****		-
10	14.0		83			-
2A	12.6	26.1	73	93	0.750	1.11
28	14.3	28.7	75	93	0.800	1.00
34	14.9	30.9	63	79	0.889	0.89
38	17.5	31.9	$\overline{n}$	89	0.800	1.00
4A	10.1	17.8	65	75	0.428	0.56
48	10.5	19.5	67	75	0.500	0.45
SA	<b>0.</b> 0	11.2	69	76	0.288	0.39
5B	13.6	22.5	70	71	0.494	0.06
6	11.7	18.3	70	73	0 <b>. 366</b>	0.17

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## SEED AND CRYSTAL DATA FOR RUN NO. 67

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Crystal	Weight	(gms)	Thicknes	s (wile)	Grout	h Rate
<u>No.</u>	Before	After	Before	After	(grame/day)	(mils/day)
14	13.1		61	***		-
18	2.2	5.0	137	229	0.19	6.1
1C	21.8	72.7	95	360	3. 39	17.7
2A	11.2		59		•••	-
28	10.5		42			-
34	19.8	70.3	73	305	3.36	15.5
38	6.4	12.9	137	226	0.43	5.9
30	14.7	61.6	68	259	3.12	12.7
44	22.2	54.8	124	301	2.18	11.8
48	24.1	59.6	112	271	2.37	10.6
5A	9.5	50.3	45	298	2.72	16.8
58	5.1	12.1	92	173	0.47	5.4
5C	17.3	52.5	96	237	2.35	9.4
6	12.3	31.9	109	234	1.31	8.3

# SEED AND CRYSTAL DATA FOR RUN NO. 68

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Crystal	Weight (gms)		Thickness	(wile)	Grow	th Rate					
No.	Before	After	Before	After	(grazs/day)	(mils/day)					
14	20.6	77.8	85	298	1.85	6.9					
18	18.9	82.9	84	297	2.06	6.9					
2A	18.2	86.2	82	340	2.19	8.3					
28	9.0	26.3	111	293	0.56	5.9					
3A	18.2	78.5	86	281	1.95	6.3					
38	19.0	81.4	79	295	2.01	7.0					
43	17.9	68.2	104	299	1.62	6.3					
48	24.4	76.6	123	348	1.69	7.3					
5 <b>A</b>	6.7	20.2	119	281	0.44	5.2					
5B	16.5	73.9	73	282	1.85	6.7					
6	9.9	37.1	89	260	0.88	5.5					

SEED AND CRYSTAL DATA FOR RUN NO. 69

Crystal Weight (grams)		(grams)	Thickness (ulls)		Growth Rate	
No.	Defore	After	Before	After	(grams/day)	(mils/day)
14	4.3	12.4	65	185	0.51	7.5
18	13.5	54.7	58	225	2.57	10.9
10	3.8	10.9	63	170	0 44	6.7
2A	15.4	59.2	76	223	2.74	6.2
28	17.1	81.5	52	250	4.02	12.5
2C	20.7	69.1	74	267	3.02	12.0
34	14.0	51.5	59	223	2.34	10.2
3 <b>B</b>	24.1	85.1	72	212	3.01	8.7
30	2.1	5.5	54	131	2.12	4.8
44	4.8	9.3	110	167	9.28	3.5
48	19.3	61.3	68	178	2.62	6.8
4C	14.2	46.7	58	194	2.03	8.5
SA	22.3	55.3	93	240	2.06	9.2
5 <b>8</b>	13.1	43.0	65	194	1.87	8.1
6	17.5	49.0	78	204	1.97	7.8

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## SEED AND CRYSTAL DATA FOR RUN NO. 79

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Sense Any CAUSING DATA FOR ANY US, 11										
Crystal	Weight	(grame)	Thicknes	• (mils)	Growt	h Rate				
No.	Before	After	Before	After	(grams/day)	(mils/day)				
14	5.2	19,40	87	242	0.34	3.7				
18	19.9	91.58	113	347	1.71	5.6				
28	13.5	109.89	59	317	2.30	6.1				
28	18.4	87.10	74	329	1.63	6.1				
34	17.5	78.71	58	283	1.46	5.4				
38	15.7	71.61	76	297	1.33	5.3				
44	21.4	88.70	83	311	1.60	5.4				
48	20.3	89.31	72	242	1 64	4.1				
5 <b>A</b>	21.2	82.42	76	288	1.46	5.1				
5B	13.6	65.37	69	284	1.23	5.1				
6	4.0	12.00	83	187	0.19	2.5				

SEED AND CRYSTAL DATA FOR RUN NO. 1

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1	AND	CITS	TAL	DATA	POR	RUN	NO.	77

Crystal	Matal Weight (gms)		Thickness (mils)		Growth Rate	
No.	Before	After	Before	After	(grame/day)	(mils/day)
14	12.9	51,70	45	215	2.16	11.3
18	18.7	61.18	62	229	2.36	11.1
28	0.6	0.58	71	79		
28	4.8	16.50	50	205	0.65	9.7
<b>2</b> C	23. 3	66.30	93	260	2.39	11.1
3A	14.6	46.10	72	215	1.75	9.5
38	20.0	59.60	66	265	2.20	13.3
4	10.2	26.75	80	214	0.92	8.9
48	14.1	46.30	63	206	1.79	9.5
5 <b>A</b>	14.7	40.53	73	199	1.38	8.4
58	21.9	57.30	72	220	1.97	9.9
6	15.0	43.93	67	182	1.60	7.7

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Crystal	Crystal Weight (gus)		Thicknes	s (mils)	Growth Rate		
<u>No .</u>	Refore	After	Before	After	(gms/day)	(alls/day)	
1A	28.8	189.8	80	629	4.3	15.7	
18	12.6	137.1	63	576	3.6	14.7	
28	3.8	35.7	52	432	09	10.8	
28	20.2	149.0	95	512	3.7	11.9	
2C	19.8	183.5	72	615	4.7	14.5	
3A	22.0	135.5	85	492	3.2	11.6	
38	9.5	81.2	61	454	2.0	11.2	
44	11.2	75.8	86	440	1.8	10.1	
48	9.2	67.3	ė9	419	1.7	10.0	
SA	36.2	109.3	95	395	2.4	8.6	
5 <b>B</b>	27.1	96.3	104	367	2.0	7.5	

SEED AND CPYSTAL DATA FOR RUN NO. 73

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Crystal	tal Weight (gms)		Weight	Weight (mils)		Growth Rate		
NO,	Before	After	Before	After	(gas/day)	(ails/day)		
14	10.4	112.9	27	435	3.3	12.8		
18	16.2	129.0	59	465	3.0	13.1		
24	20.2	133.8	67	477	3.7	13.2		
28	16.9	128.5	62	420	3.6	11.5		
AC	15.6	90.8	78	435	2.4	11.5		
38	1.1	4.6	67	1 39				
30	8.1	66.2	47	356	1.9	10.0		
44	15.4	105.4	58	483	2.9	13.7		
48	16.3	125.6	60	462	3 <b>. 5</b>	12.0		
SA	13.5	102.2	61	410	2.9	11.2		
5B	19.0	122.6	7:	455	3.3	12.4		
6	10.4	73.1	<del>,</del>	380	1.9	9.7		

#### SEED AND CRYSTAL DATA FOR RUN NO. 74

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Crystal	Weight (gms)		Thicknes	Thickness (m:1s)		Growth Rate		
<u></u>	Betore	After	Before	After	(gee/day)	(alls/day)		
1A	9.8	98.0	71	635	2.6	16.6		
18	9.8	76.2	89	619	1.9	15.6		
2A	13.8	134.6	72	712	3.6	18.8		
28	11.2	109.4	71	613	2.9	15.9		
3A	11.8	95.6	91	702	2.5	18.0		
3 <b>B</b>	20.6	160.2	80	661	4.1	17.1		
4A	6.4	53.1	70	5 <b>93</b>	1.4	15.4		
4B	13.6	96.8	84	542	2.4	13.5		
5 <b>A</b>	9.2	60.0	90	57 <b>2</b>	2.1	14.2		
5B	12.5	75.7	80	526	1.8	13.1		
6A	9.6	52.2	88	435	1.3	10.2		
6B	16.9	73.0	129	537	1.7	12.0		
	<u>-</u>	SEED AND C	RYSTAL DATA	FOR RUN N	<u>10. 76</u>			
1	29.5	152.7	107	456	2.7	7.6		
2	<b>26</b> .0	151.8	96	455	2.7	7.8		
3	27.8	148.9	98	448	2.6	7.6		
4	14.3	128.3	50	451	2.5	8.7		
5	13.0	106.3	63	419	2.0	7.7		
6	15.8	117.1	68	390	2.2	7.7		

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Crvstal No.	Height Rofnre	After	Thicknes Before	e (mils) After	Grow (gas/day)	th R <sub>a</sub> te mils/day)
1A	7.2	95.5	67	581	2.94	17.1
15	9.8	102.4	62	518	3.01	15.2
2Å	9.6	105.0	59	535	3.18	15.9
28	17.2	124.2	83	494	3.57	13.7
AE	17.3	106.4	110	501	2.97	12.9
38	16.2	98.9	80	463	2.75	12.8
44	11.5	56.4	87	378	1.50	9.7
48	20.5	98.5	90	371	2.60	9,4
SA	9.0	41.4	6 <b>6</b>	272	1.08	6.9
5 <b>B</b>	9.3	55.0	48	256	1.52	6.9
6A	15.9	37.3	96	243	0.71	4.9
6 <b>B</b>	14.3	46.6	77	235	1.08	5.3
	-	SEED AND C	PYSTAL DATA	FOR RUN N	0. 78	
1	24.8	195.9	~,	498	2.85	7.0
2	29.1	210.5	10.	547	3.14	7.4
3	17.6	198.2	54	539	3.01	8.1
4	21.8	180.0	70	466	2.64	6.6
5	25.6	175.4	75	460	2.50	6.4
6	16.4	161.3	53	448	2.42	6.6

SEED AND TRYSTAL DATA FOR RUN NO. TT

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Crystal	weight	( // m = )	This kness	:1:)	Grow	th Pate			
No.	Betero	Atter	Bofore	After	(gms/day)	(mils/day)			
1	22.8	197	57	422	2.64	6.5			
2	29.1	194	97	5 <b>46</b>	2.50	6.8			
3	32.9	215	91	549	2.76	6.9			
4	19.2	1.85	ÓÖ	489	2.52	6.5			
5	23.3	180	79	458	2.38	5.7			
6	16.6	161	55	426	2.18	5.6			
SEED AND CRYSTAL DATA FOR RUN NO. 81									
1	8.0	43.4	86	361	1.77	13.8			
2	5.0	22.1	79	273	0,86	9.7			
3	1.9	19.4	28	218	0.88	9.5			
4	6.6	24.5	83	258	0.90	8.8			
5	5.0	24.6	75	269	0.98	9.7			
	2	SEED AND	CRYSTAL DATA	FOR RUN N	10 <u>.</u> 82				
1	11.2	130.8	45	447	2.14	7.2			
2	12.6	121.0	56	4 32	1.94	6.7			
3	20.5	144.1	82	492	2.21	7.3			
4	21.3	196.9	57	520	3.14	8.0			
5	25.3	199.7	72	450	3.11	6.8			
6	20.8	167.0	61	429	2.61	6.6			

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Crystal	Weigh Before		Thickne	•• ( <u>=:1</u> •)	Growth Pate						
			061016	After	(gms/day)	(mils/ day)					
1	6.6	34.3	90	320	. 96	7.9					
2	4.5	36.7	54	314	1.11	9.0					
3	3.1	27.7	45	293	. 85	0.0					
4	3.7	24.2	44	239	.71	6.7					
5	2.6	15.9 -	37	183	. 46	5.0					
		SEED AND C	RYSTAL DATA	FOR RUN MU	, Л. А.						
1	4.9	38.3	68	342	1.15	9.5					
2	3.7	24.8	67	343	.73	9.5					
3	4.3	31.7	66	370	_44	10.5					
4	3.2	19.8	43	241	.57	6.8					
5	3.1	14 2	69	263	. 38	6.7					
	5	SEED AND CI	RYSTAL DATA	FOR RUN NO.	85						
1	19.6	159.6	56	3 <b>92</b>	2.50	6.0					
2	42.1	192.1	128	452	2.68	5.8					
3	31.8	159.9	95	397	3.29	5.4					
4	16.6	164.2	52	400	2.64	6.2					
5	23.7	158.9	76	406	2.40	5.9					
6	28.1	151.0	77	340	2.19	4.7					

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#### Crystal Lineth Testicus E.

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External Fill-	85%
Internal Fil	935
Baffle Area	-7.55
Capacity of Silver Can-	3.353 Liter
Weight of Nutrient	<u>1</u> 700 m
luminum added ' prevent Ag corresion	••2 0 gm

Figure 43 shows the crystals grown in Run No. 76. The crystals shown here are typical of the size and quality of crystals grown using the conditions given above. The cracks and other defects visible in the photograph are at the interface of the grown crystal and the seed. When cut along the interface large slabs of crack-free material is obtained.

#### 3 2.4 Silver Corrosion

From the very beginning of the hydrothermal crystal growth program the problem of sliver corrosion appeared. Corrosion of the cans was a serious problem not only because of possible autoclave damage but also because the silver was chemically transported and subsequently deposited as crystalline silver. These silver crystals appeared on the can top, seed rack and were even included in the crystals. In addition to this, spectrographic analysis of clear crystals revealed the presence of silver in the crystal as an impurity, Table XIV. The effect of such silver on the electrical or acoustical properties of the crystals is not certain.

The approaches to reducing or eliminating this corrosion were undertaken until the solution was finally found. Landers and Koib<sup>14</sup> at Bell Telephone Laboratories working with essentially the same system and conditions for the growth of ZnO crystals had never encountered this silver corrosion problem. The only outstanding difference between the two systems was that the Bell Telephone Laboratories autoclaves have a permanent silver liner. The liner is fabricated from "vacuum melted oxygen-free silver," mereafter referred to as VMOF silver. The silver used for the can, baffle, etc. at Airtron was high purity silver.

VMOF silver was purchased and in the first run in which it was used there was little or no silver attack (Run No. 63.) In this run, however, it was quite clear that the  $\Delta T$  was low as seen from the (in growth rate of 1.2 mils/day). In the following runs where a higher  $\Delta T$  was employed the extent of silver corrosion with VMOF silver was as great as it had been with the fine silver.



Figure 43 - High Quality Crystals from Run No. 76

## TABLE HTV

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#### SPECTROGRAPHIC ANALYSIS FOR HYDROTHERMALLY GROWN ZnO

#### Ledoux & Co. Analysis No. 844547

and the second sec	Crystal from Run No. 55 (Regular Can)	Crystal from Run No. 59 (Gold Plated Can)
Silver	0.03%	0.003%
Aluminum	0.005%	0.005%
Gold	ND < 0.01%	ND < 0.01 %
Zinc	High	High

Other elements not detected. High - indicates 10 - 100 %ND < - not detected less than.

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#### Trystal Treth (Continued)

The second approach to eliminating the silver corrosion was to replace silver with another noble metal. Since platinum or gold would be excessive in cost an alternate approach of gold plating the internal surfaces of the cans was used. Nu-Line Industries inc + electrochemically gold plated the can, bafile and seed rack with approximately 0.2 mils thick gold. This can was used in Run No. 59.

The crystals grown on the better seeds in this run were very high quality crystals showing little or no flawing and were completely transparent. The outstanding feature of the crystals was the color of the crystal in the <0001> direction. Instead of the normal buff color, this part of the crystal was emerald green and as a result the whole crystal appeared to be that color. The <0001>side of the crystal was the usual pale green.

Examination of the ladder, baffle and walls of the can revealed that almost all the gold plating on the baffle and ladder had been dissolved away, but that the walls had not been attacked to any extent. The nature or cause of this dissolution of gold is not known. Why the dissolution was limited to the ladder and baffle is also unknown. There was no evidence of gold deposits anywhere as had happened in the case of the silver corrosion. There was also no evidence of silver attack.

Considering the gold dissolution and appearance of a new green color to the crystal, it seemed obvious that the two were related However, x-ray fluorescence and spectrographic analyses were performed on a sample of this material, and also a crystal from Run No. 59 for comparison, and neither technique revealed the presence of gold in either sample. The limits of detection were about 1,000 ppm <sup>-</sup> for the x-ray fluorescence and 100 ppm for the spectrographic analysis. The data from the spectrographic analysis are presented in Table XIV. Aside from not detecting any gold, the effectiveness of the gold plating is shown in order of magnitude decreases in the silver content.

The cause and solution to the problem was indicated from several observations:

- 1. Increases the size of the system, increases the extent of the silver attack
- 2. The larger the  $\Delta T$ , the greater the reaction
- 3. Use of oxidizing agents in other hydrothermal systems the subscription of the silver attack

+ Nu-Line Industries Inc., 1015 South Sixth Street, Minneapolis, Minnesota 55415 n the second second

Considering the shows to the it was clear that a reducing agent should be tried. Since serve was operant mined it should be more reactive toward exidizing edites than silver and when exidize 1 would form Ze lons which are already present in the solution. Run No. 71 was the first run in which a small piece ( $\sim$  2-3 gm) of zinc metal was scaled in the nutrient section of the can. There was no trace of pilver deposit or corrosion anywhere in the system. In every run after that to which zinc metal was added there was no corrosion.

The mechanism by which the silver corrosion appears is as follows. The initial attack on silver is caused by oxygen dissolved. in the KOH solution and in the air entrapped in the silver can during its closure. In the nutrient zone, the hottest part of the can, a soluble silver complex is formed which is convectively transported to the cooler regions of the can. Because of thermal disturbance of the equiplibrium a dispreportionation reaction occurs which yields metallic silver and a silver complex of higher oxidation number.

Similar thermally dependent disproportionation reactions are popularly used for the vapor phase growth of III-V compounds. The lack of thermodynamic data for the possible cilver species at the elevated pressures and temperatures makes it impossible to assign definite oxidation states to the silver in the transporting complex ions. In this system the silver was principally deposited in the two regions where the temperature drops are greatest, at the baffle plate (its purpose is to divide the fluid into two temperature regions), and the top of the can where the heat loss to the ambient is greatest.

This proposed mechanism explains the initial fliver attack, its continued transport during the course of a run, and the observations which lead to using a reducing agent.

The added zinc metal is effective since it probably reacts with the enclosed oxygen and water to form zinc (II) ions and hydroxide ions, both of which are already present in the solution. Any zinc metal in excess of the amount that is not oxidized by the oxygen reacts with the fluid to form hydrogen.

The solving of silver corrosion in this system is important since it also provides a possible solution to noble metal corrosion in other systems. For example although the silver attack in the hydrothermal ruby system is not as extensive, the addition of metallic aluminum completely eliminates any trace of silver deposits.<sup>15</sup> Yttrium metal should also eliminate the silver attack in the hydrothermal growth of  $Y_3Fe_5O_{12}$ .

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#### THE PERMIT

#### 4.1. Presentity Mondur Lope Technique

The apparatus used to measure electrical resistivity was minitur to that used by Kolb and Laudise,<sup>10</sup> using the V-I technique. In this technique a measured d.c. current is made to pass through the sample and the voltage drop is measured, the sample resistivity is calculated from the voltage, urrent, and dimensions of the sample.

The circuit diagram of the set-up is shown in Figure 44. The jig for holding the sample was enclosed in a metal box to provide electrical and light shielding of the sample during measurement. The jig for holding the sample was FF-91 formida and the sample contacts were a brass pin and golu foil. The direct current source was provided by four 7 v batteries connected in series. The current and voltage were measured by means of two meters: 1) Keithley Hodel 150A Microvolt Ammeter for small currents and voltages; and 2) a Triplett Model 800 multipurpose meter for the large currents and voltages. By appropriate interchanges of the meters, the entire range of resistivities  $(10^{-3} - 10^{12})$  ohm cm) could be measured.

The sample was prepared by machining a parallelopiped typically about 7mm x 2.5mm x 1mm. The ends were then abraded and two opposing sides coated with a Hg-in alloy for contacts.

The resistivity measurements are presented in Tables XV and XVI. In some cases a large photo effect has been noticed. In all cases where this has appeared the reported measurement was not made until after photo effects had de ayed (usually more than 24 hours). This photo effect is not new. It is interesting that in some crystals a large effect is noted; whereas, in others there is little or no effect

#### 4.2 Doping

#### 4.2.1 Lithium

As already pointed out it is fortunate that the Li<sup>+</sup> ion in ZnO acts both as an impurity improving crystal quality and to generate an acceptor center so that compensation may be attained. The majority of runs made during the lifetime of the contract all employed lithium as dopant with the exception of an indium doped run and several copper doped runs.

Having obtained good sound crystals of reasonable size, resistivity samples of both the  $c^+$  side and  $c^-$  side were cut from a crystal of each run. In general the crystals from the  $c^+$  side were of high resistivity i.e. >104 cm. On the other hand the  $c^-$  side was of low resistivity <10- cm. The difference is obvious due to the way in which the Li<sup>+</sup> and zinc are incorporated just as the anisostropy in growth rate, etc. Spectroscopic analysis for lithium on both sides of the crystal, however, did not reveal sufficiently large difference in concentration to account for the orders of magnitude differences in resistivity.



TABLE XV

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RESISTIVITY MEASUREMENTS



**##** Measured perpendicular to c-axis.

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#0.1 m In(CH)3 added to solvent

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68	68- 6	67-5A 🏶	66-5B	66- 5B	65- <b>4</b> B	65-48	64-2B	6 <b>4</b> -5A	63-44	62-3	62-2A	59-4B	59- 3B	Crystal No.
° ,	°+	ł	•	° +	0,	•+	°,	°+	° 4	. °,	°+	°,	∩ +	Crystal Orientation
19,500	19,500	19,500	19,700	19,700	9,700	9,700	19,400	19,400	9,000	23,000	23,000	000,6	9,000	Pressure (psi)
066	<b>39</b> 0	389	371	371	316	316	388	388	317	390	390	313	313	Teryst (°C)
8.3	8.3	8 8 1 1	16.5	16.5	8.1	8.1	12.6	12.6	2.7	24.0	24.0	<b>6</b> .0	6.0	<0001> Grcwth Rate [miliy/day]
1.5	1.5	1.0	1.0	1.0	1.0	1.0	0.2	0.2	1.0	0.2	0.2	1.0	1.0	
6.1 × 10 <sup>-2</sup>	$1.8 \times 10^{4}$	4.4 $\times 10^{1}$	9.2 d 10-4	1.6 × 10 <sup>10</sup>	9.6 × 10 <sup>-1</sup>	7.5 x 10 <sup>8</sup>	4.9 x 10 <sup>-1</sup>	$2.5 \times 10^7$	1 x 10 <sup>3</sup>	$1.3 \times 10^{-1}$	$1.9 \times 10^{5}$	4.6 x 10 <sup>-2</sup>	1.05 x 10 <sup>4</sup>	Before Hear Treat
6.3 x 10 <sup>2</sup>	9.8 x 10 <sup>5</sup>	7.2 x 10 <sup>2</sup>	4.8 x 10 <sup>0</sup>	$1.7 \times 10^{5}$	$1.2 \times 10^{()}$	2.5 x 10 <sup>3</sup>	1.6 x 10	2.1 × 10 <sup>5</sup>	3 x 10 <sup>5</sup>	$5.2 \times 10^{l}$	3.45 x 10 <sup>5</sup>	ن 2.0 × 10	6 1.45 x 1)	After Heat Trest
1.0 x 10 <sup>4</sup>	5.4 × 10 <sup>1</sup>	1.6 × 10 <sup>1</sup>	5.25 x 10 <sup>3</sup>	1 × 10 <sup>-5</sup>	1.3 × 10 <sup>()</sup>	3 x 10 <sup>-4</sup>	$3.3 \times 10^{1}$	8 x 10 <sup>-3</sup>	3 x 10 <sup>2</sup>	4.1 y $10^2$	1.8 × 10 <sup>0</sup>	$4.4 \times 10^{1}$	$1.4 \times 10^2$	N and
None	Low	None	None	High	None	High	Low	Hìgh	Low	None	Low	Low	Low	Fifecte

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TABLE XVI

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RESISTIVITY MEASUREMENTS

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Photo Bifects	Verv high	None	High	None	Lou	None	None	None	Slight	None	Mone	None	Nora	None	None	None	Nane
ALL BLT	2.48 × 10 <sup>-3</sup>	1.06 × 13 <sup>2</sup>	C × 10	1.86 × 10 <sup>2</sup>	3.3 × 10 <sup>4</sup>	2.8 x 10 <sup>6</sup>	1 × 10 <sup>1</sup>	2.06 × 10 <sup>1</sup>	5.69 × 10 <sup>-1</sup>	3.31 × 10 <sup>0</sup>	1.425 × 10 <sup>0</sup>	3.4 × 10 <sup>0</sup>	5.6 × 10 <sup>-1</sup>	2.66 × 10 <sup>0</sup>	3.01 × 10 <sup>-6</sup>	1.44 × 10 <sup>4</sup>	6 3 8 9
After Heat Treat (ohm cm)	1.24 × 10 <sup>5</sup>	4.07 × 10 <sup>0</sup>	1.33 × 10 <sup>8</sup>	7.84 × 10 <sup>0</sup>	<b>3.24</b> × 10 <sup>2</sup>	1.06 × 10 <sup>6</sup>	9.3 × 10 <sup>2</sup>	2.99 × 10 <sup>0</sup>	2.63 × 10 <sup>3</sup>	<b>3. M x</b> 10 <sup>0</sup>	2.61 × 10 <sup>-1</sup>	1.27 × 10 <sup>1</sup>	1,06 × 10 <sup>9</sup>	8.77 × 10 <sup>1</sup>	1.60 × 10 <sup>4</sup>	2.10 × 10 <sup>3</sup>	Sample Dearepitnted
Before Heat Treat (ohm cm)	5 x 10 <sup>8</sup>	4.6 × 10 <sup>-2</sup>	4.2 × 10 <sup>7</sup>	4.2 × 10 <sup>-2</sup>	9.84 × 10 <sup>-1</sup>	3.8 × 10 <sup>-1</sup>	9.3 × 10 <sup>1</sup>	1.44 × 10 <sup>-1</sup>	4.46 × 10 <sup>3</sup>	1.01 × 10 <sup>0</sup>	1.83 × 10 <sup>-1</sup>	4.6 × 10 <sup>0</sup>	1.9 × 10 <sup>3</sup>	1.04 × 10 <sup>1</sup>	5.58 × 10 <sup>9</sup>	1.46 × 10 <sup>-1</sup>	3.9 x 10
L1 CH Conc.	6.3	8.3	8.5	12.0	5.4	5.4	9.7	9.7	11.5	11.9	12.0	12.0	15.0	15.0	7.8	7.8	10.9
<pre>&lt;0001&gt; Growth Rate (mile/day)</pre>	1.0	1.0	1.0	1.0	1.0	1.0	đ	đ	8	£	0	a	8	8	1.0	1.0	ð
Teryst (°C)	320	320	389	389	275	275	284	284	333	858	0.8	270	332	332	272	272	10 10 10 10 10 10 10 10 10 10 10 10 10 1
Pressure (psi)	9100	0016	19800	19800	33400	33400	2:1300	23300	15700	15700	28200	28200	16900	16300	24500	24500	13400
Crystal Orientation	+ <sub>0</sub>	'u '	<b>*</b> U	' U <sup>4</sup>	U	'0	<b>+</b> υ	່ບ	<b>*</b> o	'a	۰ <b>۰</b>	•0	<b>*</b> o	۰	<b>*</b> ن	1 <sub>0</sub>	U
Crystal No:	69-3A	69-2V	70-40	70- <b>2</b> C	12-34	VE-11	73-28	72-2B	73-3A	73-3A	14-34	74-6	75-3M	75- 3A	76-3	16-3	<b>77-6</b>
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84-2	84-2	6 F 0	89.2	81-3	77-6	Crystal No.
0,	°+	ο,	°+	°+	ο,	Crystal Orientation
22400	22400	25000	25000	22500	13400	Pressure (pei)
296	296	293	293	. 297	384	Teryst (°C)
0.4	0.4	0.75	0.75	1.0	5	COOOI> Growth Rate (wile/day)
8.6	8.6	7.4	7.4	<b>10.</b> 2	10.9	Li OH Conc
2.2 x 10 <sup>-2</sup>	2.7 x 10 <sup>8</sup>	5.1 x 10 <sup>-2</sup>	6.3 x 10 <sup>3</sup>	1.5 x 10 <sup>5</sup>	4.1 $\times$ 10 <sup>1</sup>	d) Before Heat Treat (ohm cm)
$2.4 \times 10^{1}$	6.0 x 10	9.44 x 10 <sup>0</sup>	2.7 x 10 <sup>5</sup>		7.47 x 10 <sup>1</sup>	After Heat Treat (ohm cm)
1.1 × 10 <sup>-3</sup>	$2.2 \times 10^{-4}$	$1.86 \times 10^2$	4.28 $\times$ 10 <sup>1</sup>		1.82 × 10 <sup>0</sup>	о К 115
None	 #	None	Low	Low	None	Phuro Brfects

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### Doping and Electrical Properties (Continued)

As the contract proceeded and the measurement was refined, heat treatment of the resistivity samples was also carried out. The purpose of the heat treatment was to diffuse out or to locate on lattice sites the residual interstitial zinc or lithium. In any case In-Hg amalgam was removed from the sample which was then placed on inert substrate. The sample was then heated in air for 50 hours at 800 °C. After this time the resistivity was remeasured.

Until the silver corrosion problem was solved the samples would exhibit very large photo conductivity effects on the  $c^+$  side. Analysis of the crystals has shown that these crystals contained significant amounts of silver and the photo conductivity has been attributed to the presence of such silver. Once the corrosion was eliminated very little or no photo effects were noted. Also of interest is that the  $c^+$  side of crystals grown during the silver corrosion period were buff colored while those which were silver free were colorless. The  $c^-$  side in all cases was pale green.

Throughout the course of the work attempts were made to relate the resistivity of the crystal to any and all of the growth parameters. Since Laudise and Kolb<sup>10,17</sup> had shown a relationship of resistivity after heat treatment to lithium content this same attempt was made to crystals grown during this work. No relationship was established. Only in the case where lithium was omitted from the fluid (Run NG. 74) was a significant difference in resistivity noted. Otherwise there is no apparent relationship of resistivity to lithium content. As stated previously the growth conditions for most runs varied quite significantly making it difficult to compare results. Work performed at the end of the contract and since that time may help shed some light on the reasons for being unable to relate and interpret the resistivity results.

Dr. Hickernell of Motorola, Electronics Division, Scottsdale, Arizona was in receipt of several samples of ZnO. Among these were one lithium doped sample (76-5) and two copper doped samples (73 and 75-48). Dr. Hickernell measured the resistivity of this sample (76-5) and found it to be 0.5-2x10<sup>6</sup>A cm which is about two orders of magnitude greater than an Airtron measurement on crystal 76-2. While somewhat disturbing, the difference is not surprising as will be discussed in section 4.3. Dr. Hickernell also attempted to measure the mobility of this sample but its resistivity was too high for a good measurement. Acoustic velocity measurements were also made on these samples and are summarized in Table XVII.

### 4.2.2 Copper Doping

Copper, like lithium. serves to produce acceptor centers which can increase the crystal resistivity. The objective in attempting copper doping in the ZnO crystal growth was to produce crystals in the  $10^3 - 10^5$  cm region.

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TABLE XVII

# ACOUSTIC VELOCITY MEASUREMENTS

## OF COPPER DOPED ZINC-OXIDE

Sample Designation	Propagation Mode	<b>Propagation</b> Direction	Particle Displacement	Velocity Value (x 10 <sup>5</sup> cm/sec)
73	Shear	// с	1C	2.747 + .002
75-4B	Ç,,,			
	Sileat	// C	10	2.733 + .005
	Shear	1C	10	2.794 + .005
76-5	Shear	// c	10	2.737 + .005
	Shear	1		
	3			200. + 208.2
	Shear	10	// c	2.835 + .002
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### Doping and Blectrical Properties (Continued)

The first run, No. 72, was successful in producing lower resistivity material. In this run 24 grans of CaO were added to the nutrient. The complete operating conditions for all the copper doped runs are presented in Table XI. The growth temperature in this run was 284°C with a  $\Delta T$  of 24°. After the runs there was evidence of CuO crystals in the growth chamber indicating that the solution had been saturated, thus limiting the amount of copper ions available for incorporation into the ZnO crystals. The resulting crystals were fairly high quality, with the c<sup>\*</sup> side having a pale brown color and the c<sup>\*</sup> side being dark green.

The resistivity of the c<sup>+</sup> side was 100-G cm and on heat treatment increased to 1000-G cm. The second seco

In order to increase the amount of copper in the next run, the crystallization temperature was increased from 284°C to 333°C. Two such runs (Nos. 73 and 75) were made in which 30.0 grams of CuO (No. 73) and 26.1 grams of CuO and 3 grams of copper metal (No. 75) were added to the nutrient. The crystals were high quality and had resistivities of about 1000-2-cm which did not increase substantially on heat treatment.

The crystallization temperature in Run No. 77 was increased to  $384^{\circ}$ C trying to raise the resistivity to  $10^{4}$  A cm or greater. In the run, the crystal quality deteriorated to the point where it was difficult to find a section sufficiently large to fabricate a resistivity sample. A piece measured 4 x  $10^{3}$  C m which on heat treatment completely decrepitated. Thus it appeared that further increasing of the crystallization temperature would not increase the degree of compensation and the crystal quality would probably continue to degenerate.

Dr. Hickernell measured the resistivities in the low  $10^{-1}$  cm range for the crystals from runs Nos. 73 and 75 which were in agreement with the Airtron measurements. Dr. Hickernell also measured the mobility of these two samples and obtained values of 161 cm<sup>2</sup>/volt sec and 136 cm<sup>2</sup>/volt sec for Nos. 73 and 75 respectively. Airtron's mobility measurement on the heat treated sample from run No. 72 was 152 cm<sup>2</sup>/volt sec. Dr. Hickernell determined the electromechanical coupling factor, K<sub>15</sub>, for crystals 75-6 and obtained a value of 0.26 which he compared with values of 0.24 - 0.28 which we had measured on lithium doped crystals.

### 4.2.3 Indium Doping

In Run No. 67.0 lm  $In(OH)_3$  was added in an effort to lower the resistivity, hopefully to  $10^3$  cm or less...Indium has been shown by Kolb and Laudise<sup>16</sup> to be a donor type impurity in ZnO. A lowering of resistivity was produced in two runs at Bell Telephone Laboratories by adding  $In(OH)_3$  to normal growth solution. The results of Run No. 67 were quite surprising. Little or no growth occurred in

### Doving and Electrical Properties (Continued)

the <0001> direction, however, lateral growth in the <1010> and <1120> direction was very extensive. In addition to the lack of a growth in the <0001> direction both sides of the seed were covered with spontaneously nucleated crystals. The spontaneously nucleated crystals were peculiar for two reasons. The usual habit or form of spontaneously nucleated crystal in the hydrothermal system is a hemimorphic nugget with nearly equal width and height. In this run, however, the crystals were much like those obtained from molten salt crystallization which have the plate like habit width <0001> faces forming the major surfaces. This habit was undoubtedly also another manifestation of impurities changing crystal growth rates.

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The second peculiarity of the spontaneous nucleation was that the crystals occurred principally over the original seed crystals and were not over any of the new lateral growth, Figure 45. Figure 46 shows another crystal from this same run but with the spontaneously nucleated crystals scrapped away from the surface. The extent of lateral growth and lack of (0001) growth is clearly shown. The lateral growth appeared to be of quite high quality and was a pale blue-green color. The spontaneously nucleated plates were also of the same color.

In addition to the spontaneous nucleation on the seeds, the walls of the can, ladder parts and top were blanketed by a deposit of the ZnO plates.

### 4.3 Run Uniformity and Crystal Uniformity

Considering the scatter of resistivity results from run to run the question arose as to the uniformity of the doping of crystals within a run and this uniformity within a single crystal.

Resistivity samples from four of five crystals of run Nos. 83 and 84 were cut and the resistivity measured. All samples were heat treated, and measured. Some of these have undergone three heat treatments. The results are presented in Table XVIII.

As can be seen from the data the virgin crystals show a wide range of resistivity of 10<sup>4</sup>A cm or greater. Upon heat treatment, however, this spread is reduced to one order of magnitude. Subsequent heat treatment up to three show less and less change in resistivity with each heat treatment cycle.

It appears that the initial resistivity cannot be reasonably controlled by growth conditions. Each subsequent heat treatment, either by diffusion or by site incorporation of impurities, Li<sup>+</sup>, and zinc tends to bring the sample to a final or "equilibrium" <sup>17</sup> resistivity.

Similarly a crystal, No. 84-3, was made into 12 samples to construct a resistivity map of the crystal. Figure 47 shows the map and values. As with the individual crystals there is a large spread







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Figure 46 - Crystal from Run No. 67 with Spontaneous Nucleation Removed

### TABLE XVIII

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### Resistivity Change on Subsequent Heat Treatments

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Crystal No.	Virgin	<u>H.T. No. 1</u>	<u>H.T. No. 2</u>	H.T. No. 3
83-2 c <sup>+</sup>	4.9 x $10^3$	4.5 x $10^3$	5.3 x $10^3$	$2.9 \times 10^3$
83-3 c <sup>+</sup>	3.9 × 10 <sup>2</sup>	3.8 x 10 <sup>4</sup>		
83-4 c <sup>+</sup>	$3.8 \times 10^4$	$6.1 \times 10^4$		
83 <b>-5</b> c <sup>+</sup>	9.1 x $10^5$	$3.0 \times 10^4$	$4.4 \times 10^{3}$	$1.9 \times 10^{3}$
84-2 c <sup>+</sup>	2.7 x $10^8$	$6.0 \times 10^4$	2.6 x $16^4$	$1.3 \times 10^4$
84-3 c <sup>+</sup>		3.2 x 10 <sup>5</sup>		
84-4 c <sup>+</sup>	$6.5 \times 10^4$	$8.9 \times 10^4$		
84-5 c <sup>+</sup>	7.2 x 10 <sup>4</sup>	$1.8 \times 10^4$	5.4 x 10 <sup>3</sup>	$2.8 \times 10^3$

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	84-3	3 c+
	Resistiva	ty (A-cu)
	Virgin	<u>Fist H.T.</u>
A	00	$3.2 \times 10^5$
в	$3.8 \times 10^4$	$1.7 \times 10^5$
С	$2.8 \times 10^4$	$1.2 \times 10^5$
D	$3.9 \times 10^7$	1.5 x 10 <sup>5</sup>
E	$1.3 \times 10^4$	$4.5 \times 10^4$
F	$4.6 \times 10^5$	$1.3 \times 10^{5}$
G	$5.3 \times 10^5$	$1.2 \times 10^5$
н	$1.6 \times 10^5$	$5.8 \times 10^4$
I	$4.6 \times 10^4$	$1.5 \times 10^5$
J	$4.0 \times 10^4$	$2.1 \times 10^5$
к	$2.5 \times 10^5$	8.4 x $10^4$
L	$6.7 \times 10^4$	$1.6 \times 10^4$



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Figure 47 - Resistivity Map Crystal No. 84-3

### Doping and Electrical Properties (Continued)

 in resistivity for the virgin crystal. On heat treating the spread was reduced to about one order of magnitude.

The final run made under the contract was No. 55 which was a large crystal growth run. Zinc rade for matrient preparation had been from the same lot throughout "he contract up to this run in which a new lot was used. The crystals grown using this new lot were grown in color compared to the previous coloriess material.

An analysis of both lots was obtained but no detectable differences were noted. Table XIX. Even though the ZnO is of high purity close examination of this material showed that it contained many fine foreign particles and several large pieces of metallic chips.

It appears that commercially available sinc oxide powder cannot form the basis of a process where the addition of small assumts of impurities can radically affect the electrical properties of the crystal. It also appears that no data on virgin crystals is reliable because of the large variation noted from crystal to crystal and within a crystal. Ancouraging though is the fact that on heat treatment the resistivity does appear to reach an "equilibrium" value.

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### TABLE XIX

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## Results of Spectrographic Analysis of 200

	Lot No. 1	Let No. 2
Silver	ND<0.001%	
Aluminum	ND<0 (V/1%	
Arsenic	ND-0.035	
Gold	N2<0.05%	
Boron	ND=0.0055	
Barium	ND<0.0015	
Beryllium	ND<0.0015	
Bismuth	ND-00.0011	
Calcium	ND<0.0055	
Cadmium	NDc0.05%	
Cobalt	NDrO. 001 S	
Chronium	NDrO. 0015	
Copper	NDKO 0016	
Iron	ND-0.0015	ND40.001%
Gallium		ND=0.001%
Germanium		ND<0.001%
Hafnium		ND<0.005%
Lithium		ND<0.05%
Indium		ND<0.001%
Iridium		ND<0.001%
Macnesium		ND=0.05%
Manganese	U.003%	0.005%
Molybdenum		ND<0.001%
Sodium		ND<0.001%
Columbium		ND<0.001%
Nickel		ND<0.005%
Osmium		ND<0.001%
Lead		ND<0.05%
Palladium	ND-0 0015	ND<0.003%
Platinum	ND-0.0015	ND<0.001%
Rhodium		ND<0.005%
Ruthenium		ND<0.005%
Antimony	ND-OLOSS	ND<0.05%
Silicon	ND-0.033	ND=0.05%
Strontium		ND<9.001%
Tantalum	NDRU. UUIN	ND<0.001%
Tellurium		ND<0.05%
Thallium	ND-CO.15	ND=0.1%
Titanium		ND=0.01%
Vanadium		ND<0.001%
Tungsten		ND<0.001%
Zinc		ND<0.05%
Zirconium		High
Tin		ND<0.001%
	4D<0.0012	ND<0.001%

NDc - Not Detected Less Than

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### 5.0 CONCLUSIONS

This report contains the description of the manufacturing technology required to produce large high quality crystals of sinc onide. It is a peculiar situation that with all that is known concerning ZnO and all of the interest in it as a material no device requirements for large amounts of material yet exist. It is a case where the crystal growth technology has preceded the corresponding device devopment. Purt of the reason for this may be that before this contract only small vapor grown crystals were available which were not suited for device fabrication.

The work performed in the molten salt area, though not completely successful, did provide sufficient seed material for the hydrothermal process at that time.

The hydrothermal portion of the program was quite successful in that it was demonstrated that very large crystals of high quality could be grown by this process. Although crystals doped at all resistivity levels cannot be grown as reproducibly as desired, crystals can be grown in the  $10^2 - 10^5$  range. This is the range required for acoustic amplifier devices. Furthermore crystals have been grown with very high resistivities and it may be that this area may be brought under better control.

Prior to this contract the only large crystal hydrothermally grown was quartz. The hydrothermal technique for crystal production has thus been extended and concomitantly new techniques had to be developed. In order to grow large 2nO crystals, the large silver can technique was perfected and a positive sealing procedure for the can was developed.

As opposed to quarts where acmite is generated to insure the sealing of the autoclave, only water is present in the external fill and the sealing pieces of the autocluve must be perfect if the seal is to close effectively. In order to accomplish such sealing on a routine but guaranteed basis, certain tools and techniques were evolved during the course of the program.

In addition to the new tools to be used with the autoclaves, the autoclave design itself was improved so that the manufacturer has included these modifications in this standard vessel.

Several unexpected problems were encountered during the work: one of these was silver corrosion under hydrothermal conditions. This form of corrosion had not been reported until this time. Considering the serious consequences of the corrosion it was imperative to solve the problem. The solution was achieved and similar techniques have been applied to other hydrothermal systems (Al<sub>2</sub>O<sub>3</sub>, YIG, BeO) to eliminate the corrosion in those systems.

Another problem which arose was the discovery that the phenomenon of electrical twinning occurs in hydrothermal 2nO. The formation of the twin during crystal growth could not be eliminated but twinned material

### Conclusions (Continued)

### was removed mechanically after growth.

Copper doping in the hydrothermal was first stamped and subcess schieved in producing high quality constals in the intermediate residutivity range. The largest sinc oxide crystals ever grown (15 crystals all weighing in excess of 150 grame were produced and delivered to the Air Force Materials Laboratories.

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In addition to growing and delivering the required large crystale it should be noted that throughout the course of the cor 'rant' large numbers of crystals have been made available and delivered to many researchers. These include covernment, industrial and educational laboratories whose interest varied from the measurement of fundamental preserties of ZnO to device fabrication. It is heped that material from this program will abed new light on the fundamental properties and yield a device for which crystal material is readily available.

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### 6.0 HECOMMENDATIONS FOR FUTURE MORK

Although the requirements as set forth to develop the manufacturing process, techniques and equipment for the hydrothermal growth of large 2nO crystals may been accompliabed it is clear that many facets of growth of this crystal should be investigated in greater depth.

- A fundamental study should be carried out to investigate in detail the dependence of growth rate on pressure, temperature, AT, solute concentration and impurity ion effects.
- 2) From such a study a set of conditions sight be observed which could be developed to yield a process wherein higher growth rates and higher quality crystals could be obtained.
- 3) A program is required to develop a precess which could yield on purer starting 2nO powder and also purer NON for selvent preparation.
- 4) Further improvements are required in the ability to dope at nore levels and in a more reportucible uniform manner.
- 5) A study should be carried out to dope 2nO with ions other than lithium, copper and indium to see if the objectives of No. 4 above could be more easily accomplished and/or yield a crystal with other interesting properties.
- 6) Finally a program must be carried out to develop the growth whereby crystals are produced whose major dimension lies in the <0001> axis.

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### 7.0 REFERENCES

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### DD Form 1473 Itom No. 13. ABSTRACT - continued

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In addition to the growth of the large orystals many smaller erystals were grown which were doped with copper to give resistivities in the  $10^4 - 10^4$  -2 on range. This is the range most desirable for accustical amplifier devices. Other doping studies indicate a wide variation of resistivities within the virgin crystal, and from crystal to crystal within a run. After heat treatment, hencer, the variation of resistivity is reduced to an order of magnitude or less. It was also observed that impurities not detected by spectrographic analysis may be as important in determining the resultant resistivity as deliberate doping additions and growth conditions. During the course of these contracts many samples of hydrothermally grown 2n0 were given to scientists and engineers in government, industrial and university laboratories for measurement of the fundamental properties of 2n0 and for device design and development.

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